

Electronic Components

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For Your Creative Products ELECTRONIC COMPONENTS



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☆New product



■LCD Modules

<For industrial appliances>

Model No.	Dot format H × V (dot)	Pixel pitch H × V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Power con- sumption (W) (TYP.)	Outline dimensions*1 W × H × D (mm) (TYP.)	Weight (g) (MAX.)	Remarks		
LQ035Q3DG03	320 × RGB × 240	0.2205 × 0.2205	70.56 × 52.92	16.19 M	450	CMOS	0.8	76.9 × 63.9 × 4.7	TYP. 42	Long-life LED backlight		
LQ035Q3DY01	240 × RGB × 320	0.2235 × 0.2235	53.64 × 71.52	260 k	600	CMOS	0.5	65.0 × 85.0 × 3.4	40	Advanced Super V, Low reflection technology		
LS037V7DW05	480 × RGB	0.117 x	56.16 x	16.77 M	250	CMOS	0.4	65.0 × 89.2 × 4.4	50	Advanced Super V, Transflective LCD, With resistive touch panel		
LS037V7DW06	× 040	0.117	74.00		300			65.0 × 89.2 × 3.6	38	Advanced Super V, Transflective LCD		
LQ042T1DW01	480 × 272 × RGB			16.19 M	400	CMOS	2.5	109.5 × 69.0 × 9.6	85	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit		
LQ043T1DG28	480 × 272	0.198×	95.04 ×	060 k	300			105.5 × 67.2 × 4.2	60	With resistive touch panel		
LQ043T1DG29	× RGB	0.198	53.856	200 K	360	CMOS	0.6	105.5 × 67.2 × 3.1	45			
LQ043Y1DY01	480 × RGB × 800	0.117 × 0.117	56.16 × 93.6	16.77 M	315			62.46 × 105.9 × 2.1	30	Advanced Super V, Low reflection technology		
LQ057Q3DC03	320 × 240 × RGB	0.36 × 0.36	115.2 × 86.4	260 k	500	CMOS	2.5	144.0 × 104.6 × 12.3	210	Long-life LED backlight, Built- in LED backlight driver circuit		
LQ064V3DG06	640 × 480 × RGB	0.204 × 0.204	130.56 × 97.92	260 k	350	CMOS	3.0	161.3 × 117.0 × 12.0	TYP. 200	Long-life LED backlight, Built- in LED backlight driver circuit		
☆LQ064X3LW01	1 024 × RGB × 768	0.12675 × 0.12675	129.792 × 97.344	16.77 M	350	LVDS	5.3	153.4 × 122.0 × 9.9	220	Advanced Super V, Long-life LED backlight, Built- in LED backlight driver circuit		
LQ070Y3LW01	800 × 480	0.1905 ×	152.4 ×	16.19 M	380	LVDS	2.7	170.0 × 110.0 × 9.0	TYP. 175	Advanced Super V, Long-life LED backlight		
LQ070Y3LG01	× RGB	0.1905	91.44	260 k	350	LVDO	1.8	164.9 × 104.0 × 3.9	140			
LQ084V1DG43	640 × RGB × 480	0.267 × 0.267	170.88 × 128.16	260 k	370	CMOS	4.7	221.0 × 152.4 × 9.3	340	Long-life LED backlight, Built- in LED backlight driver circuit		
LQ084S3LG03	800 × RGB × 600	0.213 × 0.213	170.4 × 127.8	16.19 M	330	LVDS	4.1	199.5 × 154.0 × 11.6	320	Long-life LED backlight, Built- in LED backlight driver circuit		
LQ085Y3DG18	800 × 480 × RGB	0.231 × 0.231	184.8 × 110.88	260 k	250	CMOS	4.1	222.7 × 133.6 × 10.0	TYP. 256	Built-in LED backlight driver circuit		
LQ091B1LW01	822 × RGB × 260	0.267 × 0.267	219.474 × 69.42	16.77 M	380	LVDS	6.8	240.0 × 86.0 × 10.0	230	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit		
LQ101K1LY05	1 280 × RGB × 800	0.1695 × 0.1695	216.96 × 135.6	16.77 M	400	LVDS	4.2	230.7 × 152.5 × 8.7	270	Advanced Super V, Low reflection technology, Long- life LED backlight, Built-in LED backlight driver circuit		
LQ101W3LG01	1 024 × RGB × 600	0.2175 × 0.2088	222.72 × 125.28	260 K	350		5.1	235.3 × 143.0 × 7.9	350	Long-life LED backlight, Built-in LED backlight driver circuit		
LQ104V1DG81/LG81	640 × RGB × 480	0.33 × 0.33			450	CMOS/ LVDS	5.6	246.5 × 179.3 × 12.5	TYP. 500	Long-life LED backlight, Built- in LED backlight driver circuit		
LQ104S1DG2C	800 × RGB	0.264 ×	211.2 × 158.4	260 k	350	CMOS	4.5	246.5 × 179.3 × 11.0	550	Long-life LED backlight, Built- in LED backlight driver circuit		
LQ104S1LG81	× 600	0.264			420	LVDS	6.1	246.5 × 179.3 × 12.5	500	Long-life LED backlight, Built- in LED backlight driver circuit		
	Model No. LQ035Q3DG03 LQ035Q3DY01 LS037V7DW05 LS037V7DW06 LQ042T1DW01 LQ043T1DG28 LQ043T1DG29 LQ043Y1DY01 LQ057Q3DC03 LQ064V3DG06 ★LQ064X3LW01 LQ070Y3LW01 LQ070Y3LW01 LQ070Y3LG01 LQ084V1DG43 LQ084S3LG03 LQ084S3LG03 LQ084S3LG03 LQ081B1LW01 LQ101K1LY05 LQ101W3LG01 LQ104V1DG81/LG81 LQ104S1DG2C	Model No. Dot format H × V (dot) LQ035Q3DG03 320 × RGB × 240 LQ035Q3DY01 240 × RGB × 320 LS037V7DW05 480 × RGB × 640 LS037V7DW06 480 × 272 × RGB LQ042T1DW01 480 × 272 × RGB LQ043T1DG28 480 × RGB × 800 LQ043Y1DY01 480 × RGB × 800 LQ057Q3DC03 320 × 240 × RGB × RGB × 800 LQ064V3DG06 640 × 480 × RGB × 768 × 768 LQ070Y3LW01 800 × 480 × RGB LQ084V1DG43 640 × RGB × 480 × 800 LQ084S3LG03 800 × RGB × 600 × RGB LQ091B1LW01 822 × RGB × 260 × 800 LQ101K1LY05 1 280 × RGB × 800 × 800 LQ101W3LG01 1 024 × RGB × 800 × RGB	Model No. Dot format H × V (dot) Pixel pitch H × V (dot) LQ035Q3DG03 320 × RGB × 240 0.2205 × 0.2205 LQ035Q3DY01 240 × RGB × 320 0.2235 × 0.2235 LS037V7DW05 480 × RGB × 640 0.117 × 0.117 LS037V7DW06 480 × 272 × RGB 0.1935 × 0.1935 × 0.1935 × 0.1935 × 0.1935 LQ043T1DG28 480 × 272 × RGB 0.198 × 0.198 × 0.198 × 0.198 LQ043T1DG29 480 × RGB × RGB × 0.117 × 0.117 0.117 × 0.117 LQ057Q3DC03 320 × 240 × 0.36 × 0.36 × 0.36 0.36 × RGB LQ064V3DG06 640 × 480 × RGB × 0.204 × 0.204 0.204 × 0.204 ★ LQ064X3LW01 1 024 × RGB × 0.12675 × 0.12675 0.1905 × 0.1905 × 0.1905 × 0.1905 × 0.1905 LQ070Y3LW01 800 × 480 × RGB × 480 × 0.267 0.267 × 0.267 LQ084V1DG43 640 × RGB × 600 × RGB × 480 × 0.231 × 0.231 × 0.231 × 0.231 LQ085Y3DG18 800 × RGB × 600 × 0.267 × 0.267 LQ101K1LY05 1 280 × RGB × 0.267 × 0.267 LQ101W3LG01 1 024 × RGB × 8GB × 0.267 × 0.267 LQ101W3LG01 1 024 × RGB × 0.260 × 0.267 LQ104V1DG81/LG81 640 × RGB × 600 × 0.264 × 0.264	Model No. Dot format H × V (dot) Pixel pitch H × V (mm) Active area H × V (mm) LQ035Q3DG03 320 × RGB × 240 0.2205 × 52.92 70.56 × 52.92 LQ035Q3DY01 240 × RGB × 320 0.2235 × 71.52 53.64 × 74.88 LS037V7DW05 480 × RGB × 640 0.117 × 74.88 53.64 × 74.88 LS037V7DW06 480 × RGB × 640 0.117 × 74.88 53.65 × 74.88 LQ042T1DW01 480 × RGB × 640 0.117 × 74.88 52.632 LQ043T1DG28 480 × RGB × 640 0.117 × 93.6 53.856 LQ043T1DG29 480 × RGB × 800 0.117 × 93.6 53.856 LQ043Y1DY01 480 × RGB × 800 0.117 × 93.6 115.2 × 800 LQ057Q3DC03 320 × 240 × RGB × 0.36 × 86.4 0.204 × 130.56 × 97.92 ★LQ064V3DG06 640 × 480 × RGB × 0.204 × 130.56 × 97.344 LQ070Y3LW01 1024 × RGB × 768 0.12675 × 129.792 × 97.344 LQ070Y3LW01 800 × 480 × RGB × 600 0.213 × 170.4 × 128.16 LQ084V1DG43 640 × RGB × 600 0.213 × 170.4 × 128.16 LQ085Y3DG18 800 × RGB × 600 0.231 × 170.4 × 69.42 <td< td=""><td>Model No. Dot format H × V (dot) (dot) (mm) Pixel pitch (mm) (mm) Active area H × V (mm) Display colors (mm) LQ035Q3DG03 320 × RGB × 240 0.2205 × 52.92 16.19 M LQ035Q3DY01 240 × RGB × 240 0.2205 × 52.92 53.64 × 71.52 260 k LS037V7DW05 480 × RGB × 640 0.117 × 74.88 53.64 × 74.88 16.77 M LS037V7DW06 480 × 272 × RGB 0.1935 × 52.632 16.19 M LQ042T1DW01 480 × 272 × RGB 0.1935 × 52.632 16.19 M LQ043T1DG28 480 × 272 × RGB 0.198 × 53.856 260 k LQ043T1DG29 480 × RGB × RGB 0.117 × 56.16 × 93.6 16.77 M LQ057Q3DC03 320 × 240 0.36 × 115.2 × 93.8 16.77 M LQ057Q3DC03 320 × 240 0.36 × 115.2 × 97.92 × 260 k 260 k ±LQ064V3DG06 640 × RGB × RGB 0.12675 × 129.792 × 260 k 16.77 M LQ070Y3LW01 800 × 480 × RGB 0.12675 × 129.792 × 768 × 16.79 M 16.79 M LQ070Y3LG01 800 × 8GB × 8GB 0.267 × 170.88 × 260 k 16.19 M LQ084Y1DG43 640 × RGB × 8GB 0.267 × 170.4 × 127.8 16.19 M</td></td<> <td> Model No. Dot format H × V (dot) Pixel pitch H × V (mm) Colors (cd/m²) (cd/m²) (rT/P) </td> <td>Model No. Dot format H × V (dot) Pixel pitch H × V (mm) Active area H × V (mm) Display lange area (cd/m²) Luminance (cd/m²) Interface (cd/m²) LQ035Q3DQ03 320 × RGB × 240 0.2205 × 252.92 70.56 × 52.92 16.19 M 450 CMOS LQ035Q3DY01 240 × RGB × 220 0.2235 × 53.64 × 52.92 260 k 600 CMOS LS037V7DW05 480 × RGB × 640 0.117 × 74.88 53.64 × 260 260 k 300 200 LS037V7DW06 480 × RGB × 640 0.1935 × 25.632 16.19 M 400 CMOS LQ043T1DG28 480 × 272 × RGB 0.1935 × 52.632 16.19 M 400 CMOS LQ043Y1DY01 480 × RGB × RGB × 0.198 × 800 0.198 × 53.856 16.77 M 300 260 k LQ057Q3DC03 320 × 240 × 240 × 0.36 × 806 0.36 × 86.4 260 k 500 CMOS LQ064V3DG06 640 × 480 × RGB × RGB v. 260 × RGB 0.204 × 130.56 × 97.344 16.77 M 350 LVDS LQ070Y3LW01 800 × 480 v. RGB v. 260 × RGB v. 260 × 97.344 16.19 M 380 LVDS <td< td=""><td> Model No. Dot format H × V (dot) Pixel pitch H × V (dot) Pixel pitch H × V (mm) Display Luminance (cdm²) Interface Sumption (W) (mm) Dot format H × V (mm) Display Luminance (cdm²) Interface Sumption (W) (mm) Dot format h × V (mm) Display Luminance (cdm²) Interface Sumption (W) (mm) Dot format h × V (mm) Display Luminance (cdm²) Interface Sumption (W) (mm) Dot format h × V (mm) Dot for</td><td> Model No. Dot format H × V (dof) M × V (mm) M × V (mm) Display area Display area Display area Display area Display (TYP) M × M × D (mm) M × V (M × M × D (M × M × M × M × M × M × M × M × M × M</td><td> Model No. Dot format H × V (dot) Pixel H × V (dot) H × V (dot)</td></td<></td>	Model No. Dot format H × V (dot) (dot) (mm) Pixel pitch (mm) (mm) Active area H × V (mm) Display colors (mm) LQ035Q3DG03 320 × RGB × 240 0.2205 × 52.92 16.19 M LQ035Q3DY01 240 × RGB × 240 0.2205 × 52.92 53.64 × 71.52 260 k LS037V7DW05 480 × RGB × 640 0.117 × 74.88 53.64 × 74.88 16.77 M LS037V7DW06 480 × 272 × RGB 0.1935 × 52.632 16.19 M LQ042T1DW01 480 × 272 × RGB 0.1935 × 52.632 16.19 M LQ043T1DG28 480 × 272 × RGB 0.198 × 53.856 260 k LQ043T1DG29 480 × RGB × RGB 0.117 × 56.16 × 93.6 16.77 M LQ057Q3DC03 320 × 240 0.36 × 115.2 × 93.8 16.77 M LQ057Q3DC03 320 × 240 0.36 × 115.2 × 97.92 × 260 k 260 k ±LQ064V3DG06 640 × RGB × RGB 0.12675 × 129.792 × 260 k 16.77 M LQ070Y3LW01 800 × 480 × RGB 0.12675 × 129.792 × 768 × 16.79 M 16.79 M LQ070Y3LG01 800 × 8GB × 8GB 0.267 × 170.88 × 260 k 16.19 M LQ084Y1DG43 640 × RGB × 8GB 0.267 × 170.4 × 127.8 16.19 M	Model No. Dot format H × V (dot) Pixel pitch H × V (mm) Colors (cd/m²) (cd/m²) (rT/P)	Model No. Dot format H × V (dot) Pixel pitch H × V (mm) Active area H × V (mm) Display lange area (cd/m²) Luminance (cd/m²) Interface (cd/m²) LQ035Q3DQ03 320 × RGB × 240 0.2205 × 252.92 70.56 × 52.92 16.19 M 450 CMOS LQ035Q3DY01 240 × RGB × 220 0.2235 × 53.64 × 52.92 260 k 600 CMOS LS037V7DW05 480 × RGB × 640 0.117 × 74.88 53.64 × 260 260 k 300 200 LS037V7DW06 480 × RGB × 640 0.1935 × 25.632 16.19 M 400 CMOS LQ043T1DG28 480 × 272 × RGB 0.1935 × 52.632 16.19 M 400 CMOS LQ043Y1DY01 480 × RGB × RGB × 0.198 × 800 0.198 × 53.856 16.77 M 300 260 k LQ057Q3DC03 320 × 240 × 240 × 0.36 × 806 0.36 × 86.4 260 k 500 CMOS LQ064V3DG06 640 × 480 × RGB × RGB v. 260 × RGB 0.204 × 130.56 × 97.344 16.77 M 350 LVDS LQ070Y3LW01 800 × 480 v. 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All products listed on this page are LED backlight models.

*1 Protrusions such as positioning bosses are not included.
(Note) Please note that the specifications are subject to change without prior notice for product improvement.

☆New product



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■LCD Modules

<For industrial appliances> (cont'd)

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Display size (cm) ["]	Model No.	Dot format H × V (dot)	Pixel pitch H × V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Power con- sumption (W) (TYP.)	Outline dimensions*1 W × H × D (mm) (TYP.)	Weight (g) (MAX.)	Remarks	
	LQ121S1DG81				260 k	450	CMOS	6.2	276.0 × 209.0 × 11.0	650	Long-life LED backlight, Built- in LED backlight driver circuit	
	LQ121S1LG84	800 × RGB × 600	0.3075 × 0.3075	246.0 × 184.5	.5	450		5.1	276.0 × 209.0	600	Long-life LED backlight, Built- in LED backlight driver circuit	
	LQ121S1LG86				260 k	1 500		12.9	× 9.1	000	Long-life LED backlight, Built- in LED backlight driver circuit	
31 [12.1]	LQ121K1LG52				16.19 M	430	LVDS	6.0	278.0 × 184.0 × 8.6		Long-life LED backlight, Built-in LED backlight driver circuit	
	☆LQ121K1LW56	1 280 × RGB × 800	0.204 × 0.204	261.1 × 163.2	16.77 M	320		5.2	278.0 × 184.0 × 10.2	550	Wide Viewing Angle Long-life LED backlight, Built- in LED backlight driver circuit	
	☆LQ121K1LG58				16.19 M	700		5.8	278.0 × 184.0 × 8.6		Long-life LED backlight, Built- in LED backlight driver circuit	
	LQ121X3LG02	1 024 × RGB × 768	0.240 × 0.240	245.8 × 184.3	260 k	1 200		9.7	259.0 × 205.0 × 7.5		Long-life LED backlight	
	LQ150X1LG11					600		8.2	331.6 × 254.7 × 9.3		Long-life LED backlight, Built- in LED backlight driver circuit	
	LQ150X1LG91				16.19 M	350		6.8			Long-life LED backlight, Built- in LED backlight driver circuit	
	LQ150X1LG96					1 050		14.8			Built-in LED backlight driver circuit	
	LQ150X1LX92	-			16.19 M	270			326.5 × 253.5 × 9.6	950	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Haze value 3%	
	LQ150X1LX95					400		10.0			Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Haze value 3%	
38 [15.0]	LQ150X1LX96	1 024 × RGB × 768	0.297 × 0.297	304.1 × 228.1		500	LVDS				Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Haze value 3%	
	☆LQ150X1LX9K					16.19 M	400					Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Polarized sunglasses supported
	LQ150X1LW12				10 M	350		10.2	331.6 × 254.7 × 9.3		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit	
	LQ150X1LW95				16.19 M	400		10.0	326.5 × 253.5		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit	
	LQ150X1LW96					500	10.0) 326.5 × 253.5 × 9.6		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit		

All products listed on this page are LED backlight models.

*1 Protrusions such as positioning bosses are not included.
(Note) Please note that the specifications are subject to change without prior notice for product improvement.

Notice
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc.

Except where specially indicated, models listed on this page comply with the RoHS Directive*. For details, please contact SHARP.
"RoHS Directive: Prohibits use of lead, cadmium, hexavalent chromium, mercury and specific brominated flame retardants
(PBBs and PBDEs), with certain exceptions.

Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

LCD MODULES

☆New product **★**Under development



■LCD Modules

<For industrial appliances> (cont'd)

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Model No.	Dot format H × V (dot)	Pixel pitch H × V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Power con- sumption (W) (TYP.)	Outline dimensions*1 W × H × D (mm) (TYP.)	Weight (g) (MAX.)	Remarks
☆LQ156T3LW03	1 366 × RGB × 768	0.252 × 0.252	344.232 × 193.536	16.77 M	400	LVDS	16.9	363.8 × 215.9 × 10.8		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
LQ156M1LG21			344.16 ×	16.19 M	300/ 350/ 400/ 600	2ch	13.6 (600cd/ m ²)	370.0 × 217.0 × 9.3	950	Long-life LED backlight, Built-in LED backlight driver circuit, With brightness control switch
LQ156M3LW01	× 1 080	0.17925	193.59	16.77 M	400	LVDS	17.9	363.8 × 215.9 × 10.8		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
☆LQ185M3LW01	1 920 × RGB × 1 080	0.213 × 0.21300	408.96 × 230.04	16.77 M	400	2ch LVDS	17.5	430.4 × 254.6 × 10.8	TYP. 1 120	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
LQ190E1LW52	1 280 × RGB × 1 024	0.294 × 0.294			450		21.7	404.2 × 330.0 × 15.0	1 850	Advanced Super V, Long-life LED backlight
LQ190E1LW72			376.32 × 301.056		350		19.6	206.0 × 222.6		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
LQ190E1LX75/T	7.1021	0.201		16.77 M	350	2ch LVDS	19.6	× 11.5	1 300	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Haze value 3%
LQ190N1LW01	1 680 × RGB × 1 050	0.24375 × 0.24375	409.5 × 255.9375		300		20.2	444.0 × 283.3 × 15.5	1 600	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
LQ201U1LW31	1 600 × XYZ × 1 200	0.255 ×	408.0 ×	256 gray scale	1 000	2ch	25.7	436.0 × 335.0	2 400	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit, Monochrome
LQ201U1LW32	1 600 × RGB × 1 200	0.255	306.0	16.77 M	330	LVDS		× 20.4		Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
LQ231U1LW32	1 600 × RGB × 1 200	0.294 × 0.294	470.4 × 352.8	16.77 M	500	2ch LVDS	65.5	530.0 × 431.5 × 23.9	4 500	Advanced Super V, Long-life LED backlight, Built-in LED backlight driver circuit
★LQ270M1LX01	1 920 × RGB × 1 080	0.303 × 0.303	581.76 × 363.6	16.77 M	500	2ch LVDS	43.5	620.0 × 407.6 × 22.0	3 800	Advanced Super V, Long-life LED backlight
		Model No.	Model No. Dot format H x V (dot) pitch H x V (mm)	Model No. Dot format H × V (dot) pitch H × V (mm) area H × V (mm) dxLQ156T3LW03 1 366 × RGB × 768 0.252 × 344.232 × 193.536 LQ156M1LG21 1 920 × RGB × 1 080 0.17925 × 344.16 × 0.17925 LQ156M3LW01 1 920 × RGB × 1 080 0.213 × 0.21300 408.96 × 230.04 LQ190E1LW52 1 280 × RGB × 1 080 0.294 × 376.32 × 301.056 LQ190E1LW72 1 280 × RGB × 1 024 0.294 × 376.32 × 255.9375 LQ190N1LW01 1 680 × RGB × 1 050 0.24375 × 255.9375 LQ201U1LW32 1 600 × RGB × 1 200 0.255 × 0.255 × 306.0 LQ231U1LW32 1 600 × RGB × 1 200 0.294 × 352.8 +LQ270M1LX01 1 920 × RGB 0.303 × 581.76 × 352.8	Model No. Dot format H × V (dot) pitch H × V (mm) area H × V (mm) Display colors ★LQ156T3LW03 1 366 × RGB × 768 0.252 × 0.252 × 0.252 344.232 × 193.536 16.77 M LQ156M1LG21 1 920 × RGB × 1 080 0.17925 × 193.59 344.16 × 193.59 LQ156M3LW01 1 920 × RGB × 1 080 0.213 × 230.04 408.96 × 230.04 16.77 M LQ190E1LW52 1 280 × RGB × 1 080 0.294 × 301.056 16.77 M LQ190E1LW72 1 280 × RGB × 1 024 0.294 × 301.056 16.77 M LQ190E1LX75/T 1 680 × RGB × 1 050 0.24375 × 255.9375 256.9375 LQ201U1LW31 1 600 × RGB × 1 200 0.255 × 0.24375 408.0 × 306.0 256.9375 LQ201U1LW32 1 600 × RGB × 1 200 0.294 × 352.8 470.4 × 352.8 16.77 M +LQ231U1LW32 1 600 × RGB × 1 200 0.294 × 352.8 16.77 M	Model No. Dot format H × V (dot) pitch H × V (mm) area H × V (mm) Display colors (cd/m²) (TYP.) ★LQ156T3LW03 1 366 × RGB × 768 0.252 × 344.232 × 193.536 16.77 M 400 LQ156M1LG21 1 920 × RGB × 1 080 0.17925 × 193.599 344.16 × 193.599 16.77 M 400 LQ156M3LW01 1 920 × RGB × 1 080 0.213 × 230.04 16.77 M 400 LQ190E1LW52 1 280 × RGB × 1 080 0.294 × 376.32 × 301.056 16.77 M 400 LQ190E1LW72 1 280 × RGB × 1 024 0.294 × 376.32 × 301.056 350 350 LQ190E1LX75/T 1 680 × RGB × 1 020 0.24375 × 0.24375 409.5 × 255.9375 300 LQ201U1LW31 1 600 × RGB × 1 200 0.255 × 0.255 408.0 × 306.0 16.77 M 300 LQ231U1LW32 1 600 × RGB × 1 200 0.294 × 352.8 470.4 × 352.8 16.77 M 500 + LQ270MH X01 1 920 × RGB 0.303 × 581.76 × 352.8 16.77 M 500	Model No. Dot format H × V (dot) pitch H × V (mm) area H × V (mm) Display (mm) nance (cd/m²) (TYP) Interface ★LQ156T3LW03 1 366 × RGB × 768 0.252 × 344.232 × 193.536 16.77 M 400 LVDS LQ156M1LG21 1 920 × RGB × 1 080 0.17925 × 193.59 344.16 × 1050 16.19 M 300/400/400/400/350/400/600 2ch LVDS LQ156M3LW01 1 920 × RGB × 1 080 0.213 × 1080 408.96 × 230.04 16.77 M 400 2ch LVDS LQ190E1LW52 1 280 × RGB × 1 024 0.294 × 376.32 × 301.056 350 350 2ch LVDS LQ190E1LW72 1 280 × RGB × 1 024 0.294 × 376.32 × 301.056 350 360 2ch LVDS LQ190N1LW01 1 680 × RGB × 1 020 0.24375 × 255.9375 300 300 2ch LVDS LQ201U1LW32 1 600 × RGB × 1 200 0.255 × 0.255 408.0 × 97 × 255.9375 16.77 M 330 LQ231U1LW32 1 600 × RGB × 1 200 0.294 × 352.8 470.4 × 352.8 16.77 M 500 2ch LVDS + LQ270M1LY01 1 920 × RGB 0.303 × 581.76 × 352.8 16.77 M	Model No. Dot format H × V (dot) Pixel H × V (mm) Active area area area a read H × V (mm) Display local colors (cd/m²) (TYP.) LUllinance (cd/m²) (TYP.) Lulli	Model No. Dot format H × V (dot) Active pitch pitch H × V (mm) Active pitch pitch pitch H × V (mm) Display colors (cd/m²) (TYP) Interface (cd/m²) (TYP) concomposition of the pitch (MY) (TYP) d C0156T3LW03 1 366 × RG8 × 768 0.252 × 344.232 × 344.16 × × 768 16.77 M 400 LVDS 16.9 363.8 × 215.9 × 10.8 LQ156M1LG21 1 920 × RGB × 1 080 0.17925 × 344.16 × × 1 080 16.77 M 400 2ch LVDS 13.6 (600cd/m²) × 9.3 370.0 × 217.0 × 9.3 LQ156M3LW01 1 920 × RGB × 1 080 0.213 × 230.04 240.9 × 9.3 16.77 M 400 2ch LVDS 17.9 363.8 × 215.9 × 10.8 LQ190E1LW52 1 280 × RGB × 1 080 0.294 × × 10.294 376.32 × 20.294 376.32 × 20.294 350 19.6 22h × 11.5 LQ190E1LW72 1 280 × RGB × 1 050 0.294 × × 10.294 376.32 × 255.9375 350 19.6 22h × 11.5 LQ201U1LW31 1 600 × RGB × 1 200 0.255 × 0.255 × 30.00 409.5 × 30.00 350 100 2ch LVDS 25.7 436.0 × 335.0 × 20.4 LQ231U1LW32 1 600 × RGB × 1 200 0.294 × 30.09 300.0	Model No. Model No. Model No. H × V (dot) Pitch H × V (dot) Pitch H × V (dot) Pitch H × V (mm) Display H × V (mm) Display (colors) Interface Sumption (mm) (mm) (TYP) (MAX)

All products listed on this page are LED backlight models.

*1 Protrusions such as positioning bosses are not included.
(Note) Please note that the specifications are subject to change without prior notice for product improvement.

<For monitors>

Display size (cm) ["]	Model No.	Number of pixels*1	Dot format H × V (dot)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Outline dimensions*2 W × H × D (mm) (TYP.)	Backlight	Remarks
80.0	☆LQ315D1JG95	8 294 400	3 840 × RGB	697.92 ×	1.07B	350	V-bv-One	734.8 × 430.0 ×	Edge-lit	Super-high resolution and High color purity (AdobeRGB100%) by using IGZO*4 LCD, Wide viewing angle:
[31.5]	☆LQ315D1VG01	0 294 400	× 2 160	392.58	10-bit	700	v-by-One	12.0 (26.5 ^{*3})	driver)	L/R 178°/ U/D 178°, Response time [G to G]: 8 ms (Typ.)

(Note) Please note that the specifications are subject to change without prior notice for product improvement.

<For digital signage displays>

Display size (cm) ["]	Model No.	Dot format H × V (dot)	Pixel pitch H × V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Interface Outline dimensions*1 W × H × D (mm) (TYP.)	Weight (kg)	Remarks	
	☆LQ695D3LG03				1 070	350				Backlight type: edge-lit LED (built-in	
	☆LQ695D3LG06	1 920 x RGB x 1 080	0.802 × 0.802	1 538.88 × 865.62	1.07B 8-bit + 2-bit FRC	500	LVDS	1 559.4 × 893.0 × 27.5	26.5±1.5	driver) SFR (60 Hz input–60 Hz output) Viewing angle (L/R / U/D): 176° / 176°	
176.56 [69.5]	★ LQ695D3LG07					700				Orientation: portrait / landscape	
	★LQ695D1VG03	3 840 × RGB ×	0.401 ×	1 538.88 ×	1.07B 8-bit +	350		1 559.4 × 893.0 ×	27.5±1.5	Backlight type: edge-lit LED (built-in driver) SFR (60 Hz input-60 Hz output)	
	★LQ695D1VG04	2 160	0.401	865.62	2-bit FRC	500	V-by-One	27.5	27.5±1.5	Viewing angle (L/R / U/D): 176° / 176° Orientation: portrait / landscape	
	LK800D3LA28				1 0 7 5	350	LVDS	1 820.2 × 1 045.3 × 34.4		Backlight type: edge-lit LED (built-in	
203.21 [80]	LK800D3LA38	1 920 x RGB x 1 080	0.9225 × 0.9225	1 771.20 × 996.30	1.07B 8-bit + 2-bit FRC	500			34.0±1.0	driver) DFR (60 Hz input–120 Hz output) Viewing angle (L/R / U/D): 176° / 176°	
	LK800D3LA48				1110	700				Orientation: portrait / landscape	
226.66	LQ900D3LA01	1 920 × RGB ×	1.038 ×	1 992.96 ×	1.07B 8-bit +	350	LVDS	2 032.0 ×	46.5±1.0	Backlight type: direct-lit LED (built-in driver) DFR (120 Hz input–120 Hz output)	
226.66 [90]	★LQ900D3LA03	1 080	1.038	1 121.04	2-bit FRC	500	LVDO	1 168.0 × 80.0	40.0±1.0	Viewing angle (L/R / U/D): 176° / 176° Orientation: landscape (LA01) : portrait/landscape (LA03)	

^{*1} Excluding FPC for connection and other protruding parts.

^{*1} Pixel means a set of each RGB dot.
*2 Excluding FPC for connection and other protruding parts.
*3 The thickness of the control board section.

^{*4} IGZO: an oxide semiconductor consisting of In (Indium), Ga (Gallium), and Zn (Zinc).

LCD MODULES

☆New product



<For wearable & mobile terminal device (low power consumption LCD)>

Display size (cm) ["]	Model No.	Dot format H × V (dot)	Pixel pitch H × V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Power consump- tion*1 (μW) (TYP.)	Outline dimensions*2 W × H × D (mm) (TYP.)	Weight (g) (MAX.)	Remarks
2.4 [0.96]	☆LS010B7DH05	192 × 192	0.127 × 0.127	ø24.384	B/W	No B/L	Serial	40	29.7 × 30.5 × 1.645 (Octagonal)	3.0	
3.05 [1.2]	LS012B7DH02	240 × 240	0.127 × 0.127	ø30.48	B/W	No B/L	Serial	50	35.78 × 36.53 × 1.605 (Octagonal)	4.4	
3.2 [1.26]	LS013B7DH05	144 × 168	0.145 × 0.145	20.88 × 24.36	B/W	No B/L	Serial	35	24.68 × 30.00 × 0.745	1.1	
3.3 [1.28]	LS013B7DH03	128 × 128	0.180 × 0.180	23.04 × 23.04	B/W	No B/L	Serial	50	26.6 × 30.3 × 0.741	1.3	
3.4 [1.33]	LS013B7DH06	128 × RGB × 128	0.186 × 0.186	23.808 × 23.808	8 colors	No B/L	Serial	60	26.82 × 31.3 × 0.745	1.5	
6.9 [2.7]	LS027B7DH01	400 × 240	0.1470 × 0.1470	58.8 × 35.28	B/W	No B/L	Serial	175	62.8 × 42.82 × 1.64	10.6	
11.2 [4.4]	LS044Q7DH01	320 × 240	0.280 × 0.280	89.6 × 67.2	B/W	No B/L	Serial	600	94.8 × 75.2 × 1.64	29.3	

 ^{*1} Data update mode (Display pattern: Vertical stripe display)
 *2 Protrusion such as positioning bosses are not included.

⁽Note) Please note that the specifications are subject to change without prior notice for product improvement.



CMOS IMAGE SENSORS FOR DIGITAL CAMERAS/ DIGITAL CAMCORDERS



■CMOS Image Sensors for Digital Cameras/Digital Camcorders

Optical format	Total pixels	Color filter	Model No.	Video performance	Resolution Image pixels (H × V)	Pixel size H × V (μm)	Sensitivity (mV/Lux-sec) TYP.	Package	
1 type	13 110 k	R, G, B primary color mosaic filters	RJ5DY1BA0LT	4K2K 60 fps	4 144 × 3 096	3.1 × 3.1	1 420	N-LCC120-R898	
rtype		B/W	RJ5DY2BA0LT				2 390		
2/3 type	2 320 k	R, G, B primary color mosaic filters	RJ52N1BA0LT	1 080p 120 fps	1 984 × 1 116	5.0 × 5.0	3 240	N-LCC120-R898A	
•		B/W	RJ52N2BA0LT				6 080		





High-Sensitivity Image Sensors for Security Usage

■Progressive CCDs

Optical	Total				Resolution	Pixel size	Sensitivity*1	Smear ratio	
format	pixels	Model No.	Video performance	Color filter	Image pixels (H x V)	H x V (µm)	(mV) TYP.	(dB) TYP.	Package
		RJ33B3AA0DT*2	VGA 120 fps	Primary color			3 000		
	350 k	RJ33B4AA0DT*2	(1 ch output)	B/W	660 x 494	7.4 x 7.4	4 500	125	P-DIP024-0400
	350 K	RJ33B3AD0DT*2	VGA 200 fps	Primary color	000 X 494	7.4 x 7.4	3 000	-125	F-DIF024-0400
		RJ33B4AD0DT*2	(2 ch output)	B/W			4 500		
	520 k	RJ3331AA0PB	NTSC 650 TV lines	Complemen- tary color	976 x 494	5.0 x 7.4	1 500	-120	P-DIP016-0450
1/3	610 k	RJ3341AA0PB	PAL 650 TV lines	Complemen- tary color	976 x 582	5.0 x 6.3	1 300	-120	F-DIF010-0450
type	1 350 k	RJ33J3CA0DT*2	1.3M 30 fps 720p 30 fps	Primary color	1 320 x 976	0.75 v 0.75	950	-120	P-DIP024-0400
	1 350 K	RJ33J4CA0DT*2	(1 ch output)	B/W	1 320 x 976	3.75 x 3.75	1 430	-120	P-DIP024-0400
	2 170 k	RJ33N3AA0LT*2	1 080p 25 fps	Primary color			470		
		RJ33N4AA0LT*2	(1 ch output)	B/W	1 928 x 1 088	2.8 x 2.8	650		N-LCC040-R350B
		RJ33N3AD0LT*2	1 080p 50 fps	Primary color			470		
		RJ33N4AD0LT*2	(2 ch output)	B/W			650	1	
		RJ31N3EA0DT*2	1 080p 25 fps (1 ch output)	Primary color	1 928 x 1 088		750		
1/2		RJ31N4EA0DT*2		B/W		3.65 x 3.65	1 150	1	
type	2 170 k	RJ31N3ED0DT*2	1 080p 50 fps	Primary color			750	- -115	
		RJ31N4ED0DT*2	(2 ch output)	B/W			1 150		
	0.100 k	RJ31N3AA0DT	2M 25 fps	Primary color			1 100		
	2 100 k	RJ31N4AA0DT	(1 ch output)	B/W	1.044 × 1.000	44444	1 650	100	D DIDOOR OFCC
	2 130 k	RJ31N3AD0DT	2M 50 fps	Primary color	1 644 x 1 236	4.4 x 4.4	1 100	120	P-DIP028-0566
1/1.8	2 130 K	RJ31N4AD0DT	(2 ch output)	B/W			1 650		
type		RJ31P3AA0DT*2	2.8M 17 fps	Primary color			750		
	0.000	RJ31P4AA0DT*2	(1 ch output)	B/W	4.0404.400	0.00 0.00	1 150	<u> </u>	
	2 960 k	RJ31P3AD0DT*2	2.8M 30 fps	Primary color	1 940 x 1 460	460 3.69 x 3.69	750	-115	
		RJ31P4AD0DT*2	(2 ch output)	B/W	1		1 150		

 ^{*1} The average G signal output voltage (the average output voltage in the case of the complementary color filter) when a 1,000-lux light source with a 90% reflector is imaged by a lens of F4 at 1/30 sec (1/25 sec in the case of RJ3341AA0PB) frame accumulation.
 *2 This model is the next-generation model. Light efficiency including the near-infrared light region has been drastically improved by our process technology.



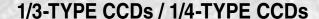
☆New product



■Progressive CCDs (cont'd)

Optical	Total				Resolution	Pixel size	Compilatività *1	Smear ratio		
format	pixels	Model No.	Video performance	Color filter	Image pixels (H x V)	H x V (µm)	Sensitivity*1 (mV) TYP.	(dB) TYP.	Package	
		RJ32S3AA0DT	5M 9 fps	Primary color			530			
		RJ32S4AA0DT	(1 ch output)	B/W	0.450 0.050		800		D DIDOOR OFCC	
2/3	5 240 k	RJ32S3AD0DT	5M 15 fps	Primary color	2 456 x 2 058	3.45 x 3.45	530		P-DIP028-0566	
type	5 240 K	RJ32S4AD0DT	(2 ch output)	B/W			800	-110		
		RJ32S3AF0DT*2	5M 30 fps	Primary color	2 456 x 2 056		580		D DIDOCA 4000	
		RJ32S4AF0DT*2	(4 ch output)	B/W			870	1	P-DIP064-1000	
		RJ3DT3AA0DT*2	6M 8 fps (1 ch output)	Primary color			1 150		P-DIP064-1000	
		RJ3DT4AA0DT*2		B/W			1 750			
	6 090 k	RJ3DT3AD0DT*2	6M 15 fps	Primary color	2 758 x 2 208	4.54 x 4.54	1 150			
1/1	6 090 K	RJ3DT4AD0DT*2	(2 ch output)	B/W	2 / 58 X 2 208		1 750	125 120		
type		RJ3DT3AF0DT*2	6M 30 fps	Primary color			1 150			
		RJ3DT4AF0DT*2	(4 ch output)	B/W			1 750			
	8 290 k	RJ3DV3AF0DT*2	8M 25 fps	Primary color	3 320 x 2 496	3.88 x 3.88	750			
	0 290 K	RJ3DV4AF0DT*2	(4 ch output)	B/W	3 320 X 2 496	3.00 X 3.88	1 100			
4/3 type	8 340 k	☆RJ3EV3EF0DT*2	8M 25 fps	Primary color	0.040 0.100	F 14 × F 14	1 500	105	D DID004 4000D	
	8 340 K	☆RJ3EV4EF0DT*2	(4 ch output)	B/W	3 848 x 2 168	5.14 x 5.14	2 250	– 125	P-DIP064-1000B	

 ^{*1} The average G signal output voltage when a 1,000-lux light source with a 90% reflector is imaged by a lens of F4 at 1/30 sec frame accumulation.
 *2 This model is the next-generation model. Light efficiency including the near-infrared light region has been drastically improved by our process technology.







■ 1/3-type CCDs

Total				Reso	lution	Pixel size	Sensitivity*1	Smear ratio	
pixels	Stan	idard	Model No.	Horizontal TV lines	Image pixels (H x V)	H x V (µm)	(mV) TYP.	(dB) TYP.	Package
270 k		NTSC	RJ2315EA0PB		512 x 492	9.6 x 7.5	4 200		
270 K		NISC	RJ2315FA0PB*2	330	312 X 432	9.0 X 7.3	4 500	-140	
320 k		PAL	RJ2325EA0PB	330	512 x 582	9.6 x 6.34	4 200	1 -140	
320 K	320 K		RJ2325FA0PB*2		312 X 302	3.0 × 0.54	4 500		P-DIP016-0450
410 k		NTSC	RJ2355DA0PB	480	768 x 494	6.4 x 7.5	2 700	135	
410 K	Color	NISC	RJ2355EA0PB*2			0.4 X 7.5	3 000		
470 1	Color	DAL	RJ2365DA0PB		752 x 582	6 52 4 6 20	2 700		
470 k		PAL	RJ2365EA0PB*2			6.53 x 6.39	3 000		
520 k		NTSC	RJ2331BA0PB		076 v 404	50×74	2 400		
520 K		NISC	RJ2331CA0PB*2	650	976 x 494 5.0 x 7.4	5.0 X 7.4	2 600	105	
C10 ls		PAL	RJ2341BA0PB	- 650 -	070 v 500	50,400	2 400	-125	
ото к	610 k		RJ2341CA0PB*2		976 x 582	5.0 x 6.3	2 600		

^{*1} The average output voltage measured when imaging a 90% reflector illuminated by a 1,000-lux light source through an optical system set at an f number of F4.0. *2 This model is the next-generation model. Light efficiency including the near-infrared light region has been drastically improved by our process technology.

■ 1/4-type CCDs

Total				Reso	lution	Pixel size	Sensitivity*1	Smear ratio	
pixels	Stan	dard	Model No.			H x V (µm)			Package
270 k		NTSC	RJ2411FA0PB	330	512 x 492	7.2 x 5.6	1 800	130	P-DIP014-0400A
320 k		PAL	RJ2421FA0PB	330	512 x 582	7.2 x 4.73	1 650		
410 k	Color	NTSC	RJ2455DA0PB	480	768 x 494	4.9 x 5.6	1 350	-120	
470 k		PAL	RJ2465DA0PB	400	752 x 582	5.0 x 4.77	1 330		
520 k		NTSC	RJ2431AA0PB	650	976 x 494	3.75 x 5.56	1 400	-120	
610 k		PAL	RJ2441AA0PB	030	976 x 582	3.75 x 4.47	1 400		

^{*1} The average output voltage measured when imaging a 90% reflector illuminated by a 1,000-lux light source through an optical system set at an f number of F4.0.





■ DSPs for CCDs

Description	Model No.		Features	Package
CDS/PGA/ADC + DSP	LR36B16	For 270-k/320-k/410-k/470-k/ 520-k/610-kpixel CCDs	<cds adc="" pga=""> High-speed S/H circuit, high-gain PGA circuit, 12-bit ADC <dsp> 75-ohm video amplifier, mechanical iris control function, 10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, LED light control function, DWDR (gamma transition function), lens shading correction function, auto white blemish compensation function, mirror image function, OSD function (5 languages: En., Ch., Fr., Por., Sp.), privacy mask function, highlight compensation, motion detection function, 2D noise reduction, high resolution function, AF detection value output, NTSC/PAL analog output, V/C analog output, UYVY digital output (ITU-R BT656 compatible)</dsp></cds>	P-HQFN072-1010

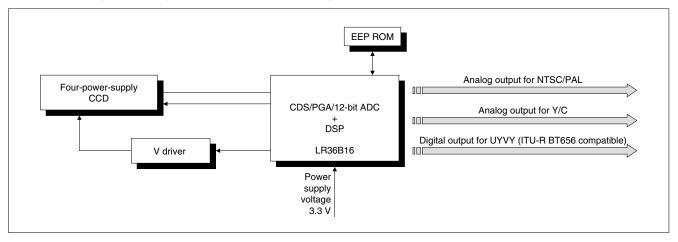






System Configuration Examples

<Color Security Camera System with Three-chip Configuration>



Four-power-supply CCDs and peripheral ICs/LSIs

-	CCD		CDS/PGA/ADC + DSP + Video amplifier
	270 kpixels	RJ2315EA0PB	
	270 kpixeis	RJ2315FA0PB	
	320 kpixels	RJ2325EA0PB	
	320 kpixeis	RJ2325FA0PB	
	410 knjvolo	RJ2355DA0PB	
1/2 tupo	410 kpixels	RJ2355EA0PB	
1/3 type	470 knivolo	RJ2365DA0PB	
	470 kpixels	RJ2365EA0PB	
	E00 knjvolo	RJ2331BA0PB	LR36B16
	520 kpixels	RJ2331CA0PB	LN30D10
	C10 kmissala	RJ2341BA0PB	
	610 kpixels	RJ2341CA0PB	
	270 kpixels	RJ2411FA0PB	
	320 kpixels	RJ2421FA0PB	
1/4 tupo	410 kpixels	RJ2455DA0PB	
1/4 type	470 kpixels	RJ2465DA0PB	
	520 kpixels	RJ2431AA0PB	
	610 kpixels	RJ2441AA0PB	

■Touch Panel Controller

● Features

1. By adopting Sharp's proprietary method, approximately eight times more sensitivity (comparison by Sharp) has been achieved compared with the conventional sequential driving method.*

Capable of sensing a ϕ 2 mm pen touch, multi-touch operation and touch operation using a glove.

2. Contributes to a thinner design of a touch panel display.

A thinner design is achievable because the design is insusceptible to the noise effect, which makes space for the sensor sheets and the display modules unnecessary.

Application Examples

PC monitor Digital signage



Multi-touch UI on a large screen for browsing or layout editing.

Interactive whiteboard **Table computer**



Multiple people can input on the screen simultaneously at educational sites, etc.

Tablet Notebook PC



Pen touch input is possible.

^{*} When comparing an S/N ratio of 3.58 determined through the conventional sequential driving method using pen-touch writing on a 20-inch screen with an S/N ratio of 30.65 determined through Sharp's proprietary parallel driving method (measured by Sharp).

TOUCH PANEL CONTROLLER

☆New product



■System LSIs



Model No.	Function	Features	Supply voltage (V)	Package
LR388K4	Touch panel controller for tablets (7 to 10 inches)	 10-finger multi-touch detection Scanning speed: 240 Hz Capable of sensing a φ2 mm pen touch USB/I²C/SPI interface Built-in palm cancellation feature 	Core: 1.2±0.12 I/O: 3.3±0.3 Analog: 3.3±0.3	P-VFBGA360P-0613

■Touch Panel Controller Module



Model No.	Function	Features	Supply voltage (V)	Outline dimensions (W × D) (mm)
LR0G964	Touch panel controller module for midium-size screens (10 to 15.6 inches)	 10-finger multi-touch detection Scanning speed: 240 Hz Capable of sensing a φ2 mm pen touch Built-in palm cancellation feature USB interface Built-in power supply circuit 	5	74 × 46
☆LR0G970	Touch panel controller module for midium-size screens (15.6 to 27 inches)	 10-finger multi-touch detection Scanning speed: 240 Hz Capable of sensing a φ2 mm pen touch Built-in palm cancellation feature USB interface Built-in power supply circuit Compatible with active pen 	5	50 × 90
LR0G967	Touch panel controller module for midium-size screens (15 to 32 inches)	 10-finger multi-touch detection Scanning speed: 240 Hz Capable of sensing a φ2 mm pen touch Built-in palm cancellation feature USB interface Built-in power supply circuit 	5	60 × 80
☆LR0G971	Touch panel controller module for large-size screens (Over 42 inches)	 50-finger multi-touch detection Scanning speed: 120 Hz Capable of sensing a φ2 mm pen touch Built-in palm cancellation feature USB interface Built-in power supply circuit 	5	100 × 220





■LED Drivers

●Built-in Step-up Circuit

Model No.	Function	Features	No. of output circuits	Number of LEDs	Booster	Constant current circuit	Switching transistor	Input voltage range (V)	Output*1 current (mA) MAX.		Package
IR2E58U	White LED driver for backlight	Capable of driving a maximum of 96 LEDs with 12 LEDs (in series) per channel Built-in step-up DC-DC converter High oscillation frequency (1.5 MHz) makes use of a small coil possible Capable of controlling brightness using PWM control Step-up output control according to LED-Vf	8	96	PWM	0	0	4.5 to 28	40/ch	500 k to 1.5 M	24HQFN
IR2E71Y	LED driver for backlight and call alert display (auto brightness adjustment)	2 ch (11 LEDs x 2 ch) LED driver for backlight Auto brightness adjustment backlight LED 6 ch RBG LED driver for illumination Built-in switching regulator for LCD backlight Built-in LCD controller power supply (+5.8 V / -5.8 V MAX.) LDO 1 ch Interface for digital-output proximity sensor with ambient light sensor Built-in general purpose input/output port (7 ch MAX.)	Backlight 2 RGB 6	Backlight 22 RGB 6	PWM	0	0	3.0 to 4.5	Backlight 25.5/ch RGB 12.7/ch	10 k to 1 M	35WL-CSP
IR2E67M	White LED driver for backlight	Built-in 10 ch. constant-current control amplifier (external output transistor) Enables driving LEDs up to external transistor voltage limit Built-in timing controller for lighting Wider range of PWM brightness control possible, from simultaneous total output control to local dimming Step-up output control according to LED-Vf	10	*2	*3	*4	External	4.5 to 5.5	*5	_	80LQFP- 1420
IR2E70N	White LED driver for backlight	Built-in step-up DC-DC controller for 2 ch individual control Capable of 2 ch individual PWM brightness control LED current value adjustable by external signal (voltage input / PWM signal) Brightness control possible at high contrast ratio 3000:1 Step-up output control according to LED-Vf	2	*2	PWM	*6	External	4.5 to 5.5 8 to 28	*5	100 k to 500 k	24SSOP

^{*1} Constant current (MAX.)

*2 Determined by external transistor voltage limit.

*3 Built-in feedback voltage-generating circuit for external power supply.

*4 Built-in constant-current control amplifier (external output transistor)

*5 Determined by external resistor.

*6 Constant current can be controlled by LED anode voltage control.



AC-DC CONVERSION TYPE ICs FOR LED LIGHTING



■AC-DC Conversion Type ICs for LED Lighting

Model No.	Features	Operating temperature	Supply voltage range	Dissipation current	Switching frequency	Gate driver capacity		System	Package
	i eatures	range (°C)	(V)	(mA) TYP.	(kHz)*1 TYP.	Low (Ω)	High (mA)	System	rackage
IR3M92N4	Overvoltage/overheat/overcurrent circuits, high-speed activation, stand-by feature, PWM brightness control		10 to 18	1	160	MAX. 15	MIN. 40	Flyback Step-down	SOP-8

^{*1} When operating a flyback converter

■CSP

●CSP (Chip Size Package)

The FBGA (commonly known as CSP) has an area array terminal structure with solder balls on the bottom, to give it a near chip-size footprint. This high-density, compact and low-profile package technology will greatly help in the design of compact mobile equipment, such as mobile phones and digital cameras.



Compact and lightweight

Ability to create a near-chip size and lighter-weight package in comparison with conventional plastic packages.

High reliability

Comparable high reliability with that of conventional plastic packages.

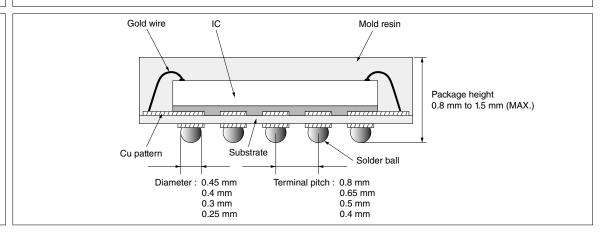
Features

● Mountability

Conventional mounting system is available for CSP. SOP and QFP can be mounted together with CSP.

Terminal pitch	0.8 mm	0.65 mm	0.5 mm	0.4 mm			
Maximum terminal counts	352 (16 mm x 16 mm)	352 (16 mm x 16 mm)	372 (16 mm x 16 mm)	264 (10 mm x 10 mm)			
Nominal dimensions	6	6 mm x 6 mm to 16 mm x 16 mm					

Cross section example



Wafer-level CSP

The wafer-level CSP (WL-CSP) is a kind of chip-size package which is manufactured by assembling directly onto the finished wafer.

Compact and thinner size

It makes it possible to create an almost IC-size and lighter-weight package.

Mountability

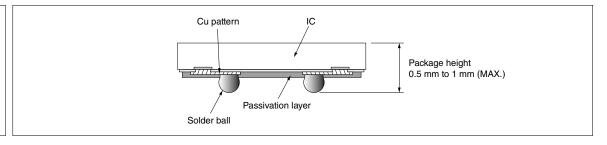
The conventional CSP mounting system can be also used in that of wafer-level CSP, which facilitates chip mounting more than bare-chip mounting does. It can be mounted together with other existing packages and passive components.

Chip size*	4 mm >	k 4 mm	3.5 mm x 3.5 mm		3 mm x 3 mm	
Pad pitch	0.5 mm	0.4 mm	0.5 mm	0.4 mm	0.5 mm	0.4 mm
Maximum terminal counts	49 (7 x 7)	81 (9 x 9)	36 (6 x 6)	49 (7 x 7)	25 (5 x 5)	36 (6 x 6)

^{*} Rectangular chip form is also available.

Cross section example

Features







■SiP (System in Package)

System in Package is SHARP's original high-density mounting technology that achieves high-density memory capacity and multiple functions by stacking multiple ICs or multiple packages. The System in Package technology means chip-stacked package technology that can achieve up to 5-chip mounting by stacking ICs in a single package. The System in Package technology contributes to higher functionality of applications, such as mobile phones and digital cameras, as well as to reduction in size and weight.

Chip Stacked CSP

Wide variety of lineup

It is possible to provide a wide lineup of stacked CSPs, including 2-chip, 3-chip, 4-chip and 5-chip stacked CSPs, to respond to customer needs.

Compact and thinner size

Encapsulating multiple ICs into an existing plastic package contributes to decreasing the mounting area. In addition, SHARP's wafer thinning technology makes it possible to achieve 1.4 mm (MAX.) package height.

Features

Multiple functions

Multiple ICs of different sizes and functions, such as logic LSIs and memories, can be incorporated in a single package, making possible multiple functions.

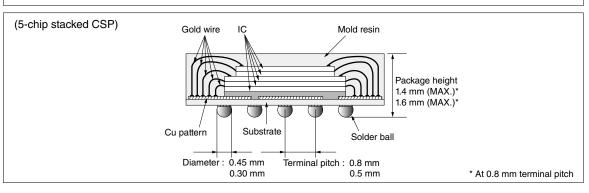
Same-size IC stacking technology

SHARP's stacking technology enables stacking of multiple same-size ICs, contributing to higher memory density.

(4-chip stacked CSP)

When using a SHARP four-chip stacked CSP, the mounting area and weight of a package can be decreased by half in comparison with using two 2-chip stacked CSPs, or a 3-chip stacked CSP and a conventional CSP.

Cross section example



●Chip Stacked TSOP/QFP*/VQFN/HQFN

Decreased mounting area

By encapsulating two identical or different types of ICs into a single conventional plastic package, the mounting area of the package can be decreased.

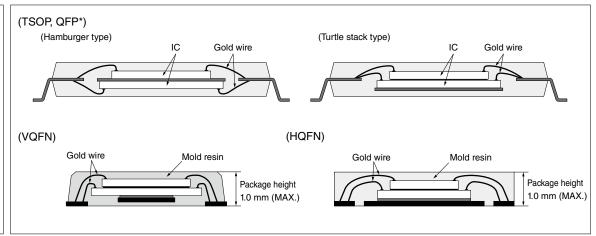
Multiple functions **Features**

Thanks to the incorporation of different sizes and functions of multiple ICs, such as logic LSIs and memories, the functionality increases.

Higher memory density

When incorporating two identical memory ICs into a single package, memory density doubles on the same mounting area.

Cross section example



Including TQFP and LQFP.





For CCDs

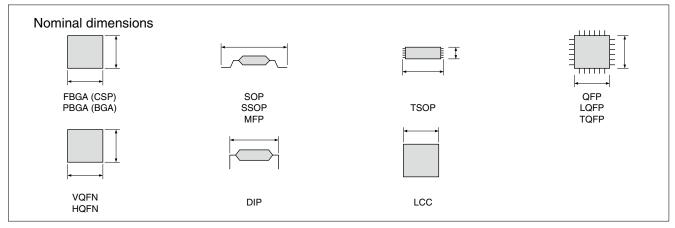
Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm (mil)	Package depth & width (D x W) x (seated height [TYP.]) mm
		P-DIP014-0400A	14	1.27	10.16 (400)	10.0 x 10.0
		P-DIP016-0450	16	1.27	11.43 (450)	11.4 x 12.2
	W	P-DIP020-0500	20	1.27	12.2 (500)	12.0 x 13.8
DIP		P-DIP024-0400	24	0.80	10.16 (400)	10.0 x 10.0
	D	P-DIP028-0566	28	1.11	14.4 (566)	14.2 x 16.0
	(Plastic)	P-DIP064-1000 P-DIP064-1000B	64	1.00	25.48 (1 000)	36.1 x 25.4
	W	P-SOP014-0400A	14	1.27	12 (470)	10.0 x 10.0 x (4.1)
SOP		P-SOP028-0400	28	0.69	10.16 (400)	10.0 x 10.0 x (3.5)
	D\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	P-SOP032-0525	32	0.78	13.3 (525)	12.0 x 13.8 x (3.92)
LCC	W (Ceramic)	N-LCC040-R350 (B)	40	0.65	8.9 (350)	8.3 x 8.9 x (1.52)
		N-LCC040-S433A	40	0.80	11.0 (433)	11.0 x 11.0 x (1.62)

100 mil = 2.54 mm

For CMOSs

Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm (mil)	Package depth & width (D x W) x (seated height [TYP.]) mm
LCC	D ((Ceramic)	N-LCC120-R898 N-LCC120-R898A	120	0.65	22.8 (898)	20.0 x 22.8 x (2.67)

100 mil = 2.54 mm



FBGA: fine-pitch ball grid array package MFP : mini flat package TQFP: thin quad flat package

PBGA: plastic ball grid array package TSOP: thin small outline package VQFN: very thin quad flat non-leaded package SOP : small outline package QFP : quad flat package HQFN: heat sink quad flat non-leaded package

SSOP: shrink small outline package LQFP: low profile quad flat package DIP : dual inline package

LCC : leadless chip carrier

Ball Grid Array and BGA are trademarks of Motorola Nippon Ltd.





■Photocoupler Lineup

<Phototransistor output type>

Package type	Output type	Features		Model No. (series)	Page
Mini-flat 4-pin Compact, SMT type	Single phototransistor	General purpose, High collector-emitter voltage		PC357NJ0000F / PC451J00000F	22
			Low input current	PC367NJ0000F	22
		AC input response		PC354NJ0000F	22
		High sensitivity,	Low input current	PC364NJ0000F	22
	Darlington phototransistor	High collector-emitter voltage		PC355NJ0000F / PC452J00000F	22
			Low input current	PC365NJ0000F	22
Compact, Half pitch (lead space), SMT type	Single phototransistor	General purpose, High resistance to noise, etc.		PC3H7J00000F	23
			Reinforced insulation	PC3HU7xYIP0B	23
***			Low input current	PC3H71xNIP0F	23
		AC input response		PC3H3J00000F / PC3H4J00000F	23
			Low input current	PC3H41xNIP0F	23
	Darlington phototransistor	High sensitivity		PC3H5J00000F	23
			Low input current	PC3H510NIP0F	23
DIP type (4-pin)	Single phototransistor	Reinforced insulation		PC123XNNSZ0F	24
(4-pin, DIP type)		General purpose,	Low input current	PC1231xNSZ0X	24
		High collector-emitter voltage, etc.		PC817XNNSZ0F / PC851XNNSZ0F	24
			Low input current	PC8171xNSZ0X	24
,	Darlington phototransistor	High sensitivity, High collector-emitter voltage		PC815XNNSZ0F▲ / PC852XNNSZ0F	24

<OPIC output type>

Package type	Output type	Features	Model No. (series)	Page
Compact, SMT type	Digital output	General purpose, High response speed	PC400J00000F	25
	Analog/Digital output	High CMR	PC457L0NIP0F	25
DIP type, SMT type	Digital output	General purpose	PC900V0NSZXF▲	26
	Built-in drive circuit	For inverter control	PC925LENSZ0F▲	26

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.







■Photocouplers

♦Phototransistor Output Type

<0	Compact, SMT	type>			O: Appro	ved								(Ta = 2	25°C)
				Approved		Absolute	maximur			Electro					
уре		Internal		by safety standards*2		Forward	Isolation voltage	Collector-	Current	transfe	er ratio	R	espon	se tim	e
Output type	Model No.	odel No. connection Features diagram		UL	Package	current IF (mA)	(AC) Viso (rms) (kV)	emitter voltage VCEO (V)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)
	PC357NJ0000F		General purpose	0		50	3.75	80	50	5	5	4	2	100	2
or outpu	PC451J00000F	DH -	High collector-emitter voltage	0		50	3.75	350	40	5	5	4	2	100	2
Single phototransistor output	PC367NJ0000F		Low input current, high resistance to noise*1	0		10	3.75	80	100	0.5	5	4	2	100	2
ingle pho	PC354NJ0000F		AC input response	0	Mini-flat	±50	3.75	80	20	±1	5	4	2	100	2
<i></i>	PC364NJ0000F	N-	Low input current, AC input response, high resistance to noise*1	0	4-pin	±10	3.75	80	50	±0.5	5	4	2	100	2
oto- put	PC355NJ0000F		High sensitivity	0		50	3.75	35	600	1	2	60	2	100	2
Darlington photo- transistor output	PC365NJ0000F		High sensitivity, low input current	0		10	3.75	35	600	0.5	2	60	10	100	2
Darl	PC452J00000F		High collector-emitter voltage	0		50	3.75	350	1 000	1	2	100	20	100	2
*1 (1)	4D: MINL 10 kV//up														

^{*1} CMR: MIN. 10 kV/µs

^{*2} Please refer to Specification Sheets for model numbers approved by safety standards.







◆ Phototransistor Output Type

	Compact, half	•	d space) SMT type>		O: Appr	oved							(Τ	Га = 2!	5°C)
				Approved		Absolute	maximu	m ratings		Electro	-optica	l cha	racteris	stics	
t type	Model No.	Internal connection	Features	by safety standards*3			voitage	Collector- emitter	Curr	ent trar	nsfer	R	espon	se tim	e
Output type	модел но.	diagram	reatures	UL	Package	current IF (mA)	(AC) Viso (rms) (kV)	voltage VCEO (V)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)		VCE (V)
	PC3HU7xYIP0B		Reinforced insulation (internal insulation distance: MIN. 0.4 mm), low-profile package	<u>*4, 5</u>	Low- profile mini-flat 4-pin	50	3.75	80	50	5	5	4	2	100	2
output	PC3H7J00000F		Standard	○*6		50	2.5	80	20	1	5	4	2	100	2
ransistor	PC3H7J00000F PC3H71xNIP0F PC3H3J00000F		High resistance to noise*1, low input current	0		10	2.5	80	100	0.5	5	4	2	100	2
le photot	PC3H3J00000F		AC input response, high resistance to noise*1	0	Mini-flat 4-pin	±50	2.5	80	20	±1	5	4	2	100	2
Sing	PC3H4J00000F		AC input response	○ *2, 6		±50	2.5	80	20	±1	5	4	2	100	2
	PC3H41xNIP0F		AC input response, high resistance to noise*1, low input current	0		±10	2.5	80	50	±0.5	5	4	2	100	2
n photo- r output	otold not obtained PC3H5J00000F PC3H5J00000F	<u> </u>	High sensitivity	0	Mini-flat	50	2.5	35	600	1	2	60	2	100	2
Darlingto transisto		<u> </u>	High sensitivity, low input current	0	4-pin	10	2.5	35	600	0.5	2	60	2	100	2



^{*1} CMR: MIN.10 kV/µs

*2 A VDE approved type is optionally available.

*3 Please refer to Specification Sheets for model numbers approved by safety standards.

*4 VDE, CSA approved

*5 In conformance with BSI, SEMKO, DEMKO, NEMKO, and FIMKO

*6 UL, cUL approved







◆ Phototransistor Output Type <DIP type (4-pin)>

- ○: Approved

 $(Ta = 25^{\circ}C)$

_					pprove			Absolut	e maximu	m ratings	Electro-	optical ch	aracte	
Output type	Model No.	Internal connection diagram	Features	safet	ĺ	dards*8 Others	Package	Forward current	Isolation voltage (AC)	emitter voltage	Current tra	IF (mA)	tr	RL (Ω)
ŏ			High isolation voltage, reinforced insulation High isolation voltage, reinforced insulation, low input current, high resistance to noise*4 High isolation voltage High isolation voltage, low input	OL.	*2	*3		(mA)	Viso (rms) (kV)	VCEO (V)	MIN.	(1114)	(µs) TYP.	(12)
+	PC123XNNSZ0F*1, *5, *6, *7		High isolation voltage, reinforced insulation	0	0	0		50	5.0	70	50	5	4	100
Single phototransistor output	PC1231xNSZ0X*1		High isolation voltage, reinforced insulation, low input current, high resistance to noise*4	0	0	0		10	5.0	70	50	0.5	4	100
ototransi	PC817XNNSZ0F*5, *6, *7		High isolation voltage	0	-	○*9		50	5.0	80	50	5	4	100
ingle pho	PC8171xNSZ0X*5, *6		High isolation voltage, low input current, high resistance to noise*4	0	-	-		10	5.0	80	100	0.5	4	100
<i>o</i>	PC851XNNSZ0F*5, *6	Diam's di		0	_	_	4-pin DIP	50	5.0	350	40	5	4	100
Darlington phototransistor output	PC815XNNSZ0F ▲ *5, *6			0	_	_		50	5.0	35	600	1	60	100
Darlington photo	PC852XNNSZ0F*5, *6			0	0	_		50	5.0	350	1 000	1	100	100
*1 *2 *3 *4 *5	Wide lead spacing type is also Optionally available. BSI, SEMKO, DEMKO, NEMK CMR: 10 kV/µs MIN. Lead forming type is also avail	(O, FIMKO, CS		le lead	d spac	ing type	: 8 mm c	or more.					•	

- Lead forming type is also available for surface mounting.
- Taped package of lead forming type for surface mounting is also available.
- Wide lead spacing type is also available. Compatible with wide lead spacing type lead-forming models for surface-mount use. Also compatible with taped packages for wide
- lead spacing type lead-forming models for surface-mount use.
 *8 Please refer to Specification Sheets for model numbers approved by safety standards.
- *9 UL, CSA approved

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.







♦ OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

<Compact, SMT type> (1-1) O: Approved (Ta = 25°C) Absolute maximum Approved by Electro-optical characteristics*1 safety ratings standards*2 Internal Isolation Low level output voltage Threshold input current Forward Model No. Features Package connection voltage current Vol **IFHL** diagram (AC) RL loi (V) MAX VDE*3 UL (mA) (mA) /iso (rms) (mA) (°C) (mA) (Ω) (mA) ŇΑΧ. ŇΑΧ (kV) Digital output, normal-off operation Mini-flat PC400J00000F 50 3.75 0.4 0 to +70 16 4 2.0 280 5-pin

- Each item is measured at Vcc=5V. (PC400)
 Please refer to Specification Sheets for model numbers approved by safety standards.
- Optionally available.

<compact< th=""><th colspan="6"><compact, smt="" type=""> (1-2)</compact,></th><th></th><th colspan="7">(Ta = 25°C)</th></compact<>	<compact, smt="" type=""> (1-2)</compact,>							(Ta = 25°C)							
			sat	ved by ety			maximum ngs			Electro	o-optic	al chara	cteristic	cs	
	Internal		standards*1		Package	Forward Isolation				ansfer ratio		Propagation		n delay time	
Model No.	connection diagram	1	UL	F		current IF (mA)	F (AC)		IF (mA)	Vo (V)	Vcc (V)	tphl (µs) TYP.	tpLH (µs) TYP.	RL (Ω)	IF (mA)
PC457L0NIP0F		High speed (1 Mb/s), high CMR (15 kV/µs), for flow soldering	0	0	Mini-flat 5-pin	25	3.75	19	16	0.4	4.5	0.2	0.4	1 900	16

Please refer to Specification Sheets for model numbers approved by safety standards.



A: Rated voltage circuit

Optionally available.



PHOTOCOUPLERS



◆OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<DIP type, digital output> O: Approved $(Ta = 25^{\circ}C)$ Absolute Electro-optical characteristics*1 Approved by maximum ratings safety Internal Threshold input standards*5 Isolation Low level output voltage Forward Model No. connection Features Package current voltage current diagram (AC) Vol **I**FLH Rμ V₽E lou UL iso (rms) (V) (mA) (mA) (mA) (°C) (mA) (mA) (Ω) (kV) MÀX ŇΑΧ. ŇΑΧ Digital output, 6-pin DIP PC900V0NSZXFA*2, *3 \bigcirc 0 50 5.0 0.4 0 to +70 16 4 2.0 280 normal-off operation

A: Rated voltage circuit

- *1 Each item is measured at Vcc=5V
- Lead forming type is also available for surface mounting.
- *3 *4 Taped package of lead forming type for surface mounting is also available.
- Optionally available.

*5 Please refer to Specification Sheets for model numbers approved by safety standards.

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.



♦ OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<DIP type, Gate drive type>

- ○: Approved

 $(Ta = 25^{\circ}C)$

,							(14 - 25 6)						
			saf				olute m ratings	Flactro-ontical characteristics			5		
	Internal		stand	ards*3		Forward	Isolation		Prop	agation	delay	time	
Model No.	connection diagram	Features	UL	VDE	Package	current	voltage (AC) Viso (rms) (kV)	tphl (µs) TYP.	tplh (µs) TYP.	Vcc (V)	IF (mA)	RL1 (Ω)	RL2 (Ω)
PC925LENSZ0F▲*1		Built-in drive circuit directly connectable to MOS-FET and IGBT Peak output current: 2.5 A Low dissipation current (Icc = TYP. 2.5 mA) High resistance to noise (CMR: MIN. 15 kV/µs)	0	0	8-pin DIP	25	5.0	MAX. 0.5	MAX. 0.5	15 to 30	7 to 16	Rg = 10	-

- *1 Lead forming type is also available for surface mounting. Taped package of lead forming type for surface mounting is also available.
- A VDE approved type is optionally available.
 Please refer to Specification Sheets for model numbers approved by safety standards.

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.





PHOTOTRIAC COUPLER LINEUP



■Phototriac Coupler Lineup

Package	Applied voltage	ON-state current (rms)		Features	Model No.	Page
Mini-flat (SMD)	AC 200 V lines (VDRM = 600V)	0.05 A	General purpose		S2S3A00F*3 / S2S5A00F*3 / S2S5FA0F*3	28
.				Built-in zero-cross circuit	S2S4A00F*3	29
DIP type	AC 200 V lines (VDRM = 600V)	0.1 A	General purpose		PC3ST11NSZKF	28
(4-pin)			Reinforced isolati	on	PC3SH11YFZAF*3 / PC3SH13YFZAF*3	2
4 4				Built-in zero-cross circuit	PC3SH21YFZBX*2	29
DIP type	AC 100 V lines (VDRM = 400V)	0.1 A	General purpose		PC2SD11NTZAF ▲ *³	28
(6-pin package, 5th-pin cut)	AC 200 V lines (VDRM = 600V)	0.1 A	General purpose		PC3SD12NTZAF*3 / PC3SD11YTZCF*1 / PC3SD11NTZCF*1 / PC3SD13YXZBF*2	28
				Built-in zero-cross circuit	PC3SD21NTZAF ^{*3} / PC3SD21NTZBF ^{*2} / PC3SD21NTZDF ^{*4}	29
			Reinforced isolati	on	PC3SF11YVZAF*3 / PC3SF11YVZBF*2	28
				Built-in zero-cross circuit	PC3SF21YVZAF ^{*3} / PC3SF21YVZBF ^{*2}	29
	AC 200 V lines (VDRM = 800V)	0.1 A	General purpose		PC4SD11NTZCF*1	28
				Built-in zero-cross circuit	PC4SD21NTZCF*1 / PC4SD21NTZDF*4	29
			Reinforced isolati	on	PC4SF11YTZBF*2	28
				Built-in zero-cross circuit	PC4SF21YVZBF*2 / PC4SF21YWPSF*2	2

Minimum trigger current: *1 IFT \leq 5 mA, *2 IFT \leq 7 mA, *3 IFT \leq 10 mA, *4 IFT \leq 3 mA The model marked with \triangle may not be available in the near future. Contact with SHARP for details before use.



PHOTOTRIAC COUPLERS



■ Phototriac Couplers O: Approved (Ta = 25°C) Electro-optical Approved by Absolute maximum ratings safety standards*4 characteristics Min. trigger Repetitive Internal Isolation peak OFF-state ON-state current Package Model No. connection Features voltage UL, CSA current **IFT** diagram VDE Others (AC) (mA) MAX. IT (rms) voltage Viso (rms) (A) VDRM VD = 6 V(kV) $R \text{L} = 100 \Omega$ (V) S2S3A00F 200 V lines, compact 0 ○*6 10 Mini-flat S2S5A00F 200 V lines, compact ○*6 0.05 3.75 10 4-pin ()*6 S2S5FA0F 0 10 High impulse noise product 600 ○*6 PC3ST11NSZKF 200 V lines, compact 0 10 200 V lines, compact, PC3SH11YFZAF 0 ^*2 4-pin 10 reinforced isolation 0.1 5.0 DΙΡ 200 V lines, compact, ○*2 PC3SH13YFZAF reinforced isolation, 10 high noise resistance PC2SD11NTZAF▲ 100 V lines 0 400 10 0 ○*6 PC3SD12NTZAF 200 V lines 10 PC3SD13YXZBF ○*6 600 High impulse noise product \bigcirc _ 7 PC3SD11YTZCF 0 ○*6 200 V lines 5 6-pin DIP*1, 3 PC3SD11NTZCF 200 V lines 0 ○*6 600 5.0 0.1 5 200 V lines, PC4SD11NTZCF ○*6 800 5 repetitive peak-OFF-state voltage PC3SF11YVZAF 200 V lines, reinforced isolation 0 0 ⊜*2 10 600 ○*2 PC3SF11YVZBF 200 V lines, reinforced isolation 0 7 \bigcirc 200 V lines, reinforced isolation, repetitive peak-OFF-state voltage PC4SF11YTZBF \bigcirc **○***2 800 7

For the notes *1 to *6, see next page.

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.





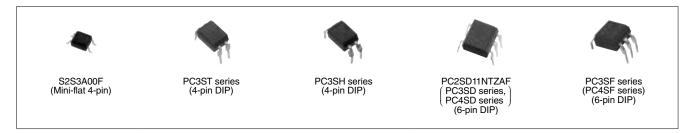
■ Phototriac Couplers

(Built-in zero	o-cross circu	uit type)			- O: Ap	proved				(Ta = 25°C)
				proved y standa			Absolut	te maximum	ratings	Electro-optical characteristics
Model No.	Internal connection dia- gram	Features	UL, CSA	VDE	Others	Package	ON-state current IT (rms) (A)	Repetitive peak OFF-state VDRM (V)	voltage	Min. trigger current IFT (mA) MAX. VD = 4 V, RL = 100Ω
S2S4A00F	Zero-cross circuit	200 V lines, compact	0	○*6	-	Mini-flat 4-pin	0.05	600	3.75	10 ^{*5}
PC3SH21YFZBX		200 V lines, compact, reinforced isolation	0	0	<u></u> ○*2	4-pin DIP	0.1	600	5.0	7
PC3SD21NTZAF		200 V lines, low zero-cross voltage: MAX. 20 V	0	○*6	-					10
PC3SD21NTZBF		200 V lines, low zero-cross voltage: MAX. 20 V	0	○*6	_			600		7
PC3SD21NTZDF		200 V lines, low zero-cross voltage: MAX. 20 V	0	○*6	_					3
PC4SD21NTZCF	Zero-cross circuit	200 V lines, repetitive peak-OFF-state voltage	0	○*6	-	6-pin		800		5
PC4SD21NTZDF		200 V lines, repetitive peak-OFF-state voltage	0	○*6	_	DIP*1, 3	0.1	800	5.0	3
PC3SF21YVZAF		200 V lines, reinforced isolation	0	0	<u></u> _*2			600		10
PC3SF21YVZBF		200 V lines, reinforced isolation	0	0	<u></u> _*2			000		7
PC4SF21YVZBF		200 V lines, reinforced isolation, repetitive peak-OFF-state voltage	0	0	<u></u> _*2			800		7
	1			_		6-pin	1	000		_

- Lead forming type for surface mounting is also available. In conformance with BSI, SEMKO, DEMKO, and FIMKO
- *1 *2 *3 *4 *5 *6
- These are molded pin No. 5.
- Please refer to Specification Sheets for model numbers approved by safety standards. V_D = 6 V, R_L = 100 Ω Optionally available

High impulse noise product

PC4SF21YWPSF



0

6-pin DIP*3



SOLID STATE RELAY LINEUP



■ Solid State Relay Lineup

	, ,				
Package	Applied voltage	ON-state current (rms)	Features	Model No.	Page
DIP 6-pin	AC 100 V lines	0.15 A	General purpose	PR22MA11NTZF▲	31
	AC 200 V lines	0.06 A	General purpose	PR31MA11NTZF	31
- 41		0.15 A	General purpose	PR32MA11NTZF	31
DIP 8-pin	AC 200 V lines	0.3/0.6/0.9/1.2 A	General purpose	PR33MF5 series / PR39MF5 series / PR36MF5 series / PR36MF5 series / PR36MF12NSZF▲	31
		0.6/0.9/1.2 A	Built-in zero-cross circuit	PR36MF2 series / PR39MF2 series	31

The model marked with \blacktriangle may not be available in the near future. Contact with SHARP for details before use.





■ Solid State Relays

<dip type=""></dip>				C	: Appro	oved				(Ta = 25°C)
				proved y stand			Absolu	te maximum	ratings	Electrical characteristics
Model No.	Internal connection diagram	Features	UL	CSA	VDE*2	Package	ON-state current IT (rms) (A)	Repetitive peak OFF-state voltage VDRM (V)	Isolation voltage (AC) Viso (rms) (kV)	Min. trigger current IFT (mA) MAX. VD = 6 V, RL = 100Ω
PR22MA11NTZF▲		100 V lines, 150 mA model in a small package	0	0	0		0.15	400		10
PR31MA11NTZF		200 V lines, compact	0	0	0	6-pin DIP	0.06	- 600	5.0	10
PR32MA11NTZF		200 V lines, 150 mA model in a small package	0	0	0		0.15	- 600		10
PR33MF51NSLF		200 V lines, compact	0	0	0		0.3			10
PR33MF52NSLF		200 V lines, compact	0	0	0		0.5			10
PR36MF51NSLF		200 V lines, compact	0	0	0		0.6			10
PR36MF12NSZF▲		200 V lines, compact, low input current	0	0	0		0.0	600		5
PR39MF51NSLF		200 V lines, compact	0	0	0	8-pin	0.9		4.0	10
PR3BMF51NSLF		200 V lines, compact	0	0	0	DIP	1.2		4.0	10
PR3BMF52NSZF▲		200 V lines, compact, low input current	0	0	0		1.4			5
PR36MF21NSZF		200 V lines, compact (built-in zero- cross circuit)	0	0	0		0.6			10
PR36MF22NSZF	Zero- cross	200 V lines, compact (built-in zero- cross circuit), low input current	0	0	0		0.0	600		5
PR39MF22NSZF	circuit	200 V lines, compact (built-in zero- cross circuit), low input current	0	0	0		0.9			5

 ^{*1} Please refer to Specification Sheets for model numbers approved by safety standards.
 *2 Optionally available.
 The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.





PHOTOINTERRUPTER LINEUP

★ Under development



■ Photointerrupter Lineup

<Transmissive type>

Output type	Package type	Outline	Mounting method	Model No. (series)	Page
Single phototransistor	Compact		PWB mounting type	GP1S396HCP0F / GP1S09xHCZ0F / GP1S19xHCZ0F	33
			Surface-mount type	GP1S396HCPSF / GP1S296HCPSF / GP1S092HCPIF / GP1S19xHCxSF	33
	Case type		PWB mounting type	GP1S5x series	34
		Horizontal slit	PWB mounting type	GP1S59J0000F	34
	With connector	General purpose	Snap-in	GP1S173LCS2F / GP1S273LCS1F	34
Digital output	Compact	High resolution	PWB mounting type	★GP1A396HCP0F	35
(OPIC output)			Surface-mount type	★GP1A396HCPSF	35
	Case type		PWB mounting type	GP1A5x series	35
		Wide gap	PWB mounting type	GP1A57HRJ00F	35
	With connector	General purpose	Snap-in	GP1A173LCS3F / GP1A173LCSVF	36

<Reflective type>

Output type	Package type	Outline	Mounting method	Model No. (series)	Page
Single phototransistor	Leadless	Long focal distance	Surface-mount type	GP2S700HCP	36
High response speed	Compact, thin (leadless)	General purpose	Surface-mount type	GP2S60	36
OPIC output	With connector	Light modulation type, Sensitivity adjusted	Screw mounting type/ Compact snap-in/ Inverter light countermeasures	GP2A25 series / GP2A28 series / GP2A200LCS0F / GP2A230LRS0F / GP2A230LRSAF / ★GP2A430LCSAF / GP2A240LCS0F / GP2A250LCS0F	37_

The model marked with \blacktriangle may not be available in the near future. Contact with SHARP for details before use.



PHOTOINTERRUPTERS (TRANSMISSIVE TYPE)



■ Photointerrupters

<Transmissive type>

♦Single Phototransistor Output

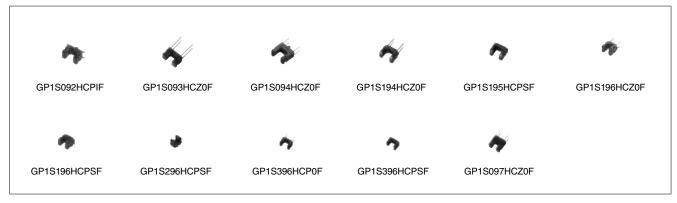
<Compact type>

 $(Ta = 25^{\circ}C)$

Model No.	Internal connection diagram	Features emitting 5	and	Slit width	Electro-optical characteristics							
					Current transfer ratio			Response ti			me	
			(mm)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (kΩ)	VCE (V)		
GP1S092HCPIF		Wide gap, for soldering reflow, surface mount compatible, with positioning boss (4.5 × 2.6 × 2.9 [height] mm)	2.0	0.3	2.0	5	5	50	0.1	1	5	
GP1S093HCZ0F		Wide gap (4.5 × 2.6 × 2.9 [height] mm)	2.0	0.3	2.0	5	5	50	0.1	1	5	
GP1S094HCZ0F		Wide gap, with positioning pin, (5.5 × 2.6 × 4.8 [height] mm)	3.0	0.3	0.8	5	5	50	0.1	1	5	
GP1S194HCZ0F		Compact, wide gap, size: 3.6 × 2.0 × 2.7 (height) mm	1.7	0.3	3.0	5	5	50	0.1	1	5	
GP1S195HCPSF		Compact, wide gap, surface mount compatible, size: 3.4 × 2.0 × 2.7 (height) mm	1.5	0.3	3.0	5	5	50	0.1	1	5	
GP1S196HCZ0F		Compact, low profile (3.1 × 2.0 × 2.7 [height] mm)	1.1	0.3	2.0	5	5	50	0.1	1	5	
GP1S196HCPSF		Surface mount, for soldering reflow, compact, low profile (3.1 × 2.0 × 2.7 [height] mm)	1.1	0.3	2.0	5	5	50	0.1	1	5	
GP1S296HCPSF		Surface mount, for soldering reflow, compact, low profile (2.5 × 1.8 × 1.9 [height] mm)	1.0	0.2	3.0	5	5	50	0.1	1	5	
GP1S396HCP0F		Straight lead type, compact, low profile (2.26 × 1.4 × 1.6 [height] mm)	1.2	0.12	2.0	5	5	30	0.1	1	5	
GP1S396HCPSF		Surface mount, for soldering reflow, compact, low profile (2.26 × 1.4 × 1.6 [height] mm)	1.2	0.12	2.0	5	5	30	0.1	1	5	
GP1S097HCZ0F		High resolution, wide gap, with mounting hole $(4.5 \times 2.6 \times 4.5 \text{ [height] mm)}$	2.0	0.3	2.0	5	5	50	0.1	1	5	

Note: Topr: -25 to +85°C

GP1SxxxHCZxF: Sleeve package, GP1SxxxHCPxF: Taped package





PHOTOINTERRUPTERS (TRANSMISSIVE TYPE)

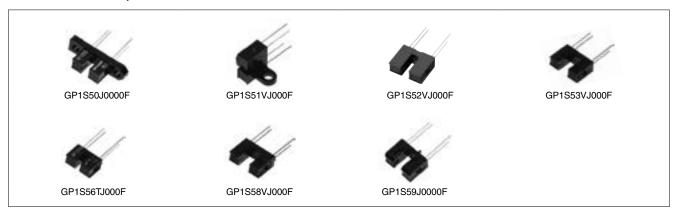


<Case type> (Ta = 25°C)

Model No.	Internal connection diagram		Detecting and emitting gap (mm)	Slit width (mm)	Electro-optical characteristics							
					Currer	t transf	er ratio	Response time				
					CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)	
GP1S50J0000F		High resolution, both-side mounting type	3.0	0.5	2.5	20	5	3	2	100	2	
GP1S51VJ000F		High resolution, side mounting type	3.0	0.5	2.5	20	5	3	2	100	2	
GP1S52VJ000F		High resolution, PWB mounting type	3.0	0.5	2.5	20	5	3	2	100	2	
GP1S53VJ000F		High resolution, PWB mounting type	5.0	0.5	2.5	20	5	3	2	100	2	
GP1S56TJ000F▲		High resolution, with positioning pin, PWB mounting type	2.0	0.15	2.0	20	5	38	0.5	1 000	2	
GP1S58VJ000F		High resolution, with positioning pin, PWB mounting type	5.0	0.5	2.5	20	5	3	2	100	2	
GP1S59J0000F		High resolution, horizontal slit, with positioning pin, PWB mounting type	4.2	0.5	2.5	20	5	3	2	100	2	

Note: Topr: -25 to +85°C

The model marked with \blacktriangle may not be available in the near future. Contact with SHARP for details before use.



<With connector> $(Ta = 25^{\circ}C)$

Model No.		Features er	Detecting and emitting gap (mm)	Slit width (mm)	Electro-optical characteristics							
	Internal connection diagram				Current transfer ratio			Response time				
					CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)	
GP1S173LCS2F		Snap-in mounting integrated connector type Applicable to 3 kinds of thickness of mounting boards	5.0	0.5	2.5	20	5	3	2	100	2	
GP1S273LCS1F		Snap-in mounting integrated connector type Applicable to 3 kinds of thickness of mounting boards Compact (Compatible with 1.5 mm pitch connector)	5.0	0.7	2.5	20	5	3	2	100	2	

Note: Topr: -30 to +95°C





PHOTOINTERRUPTERS (TRANSMISSIVE TYPE)

★ Under development

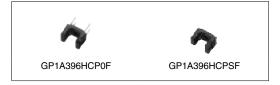


♦OPIC Type ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

<Compact type> $(Ta = 25^{\circ}C)$

			Detecting				Ele	ctro-opt	ical cha	racterist	ics		
	Internal	_	and	Slit width	Thr	eshold i	nput cur	rent		Propaga	ation del	ay time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	IFLH (mA) MAX.	IFHL (mA) MAX.	Vcc (V)	RL (kΩ)	tpLн (µs) TYP.	t _{PHL} (μs) TYP.	IF (mA)	RL (kΩ)	Vcc (V)
★GP1A396HCP0F		Compact, high response speed, digital output, PWB mounting	1.2	0.12	2.85	-	2.5 to 5.5	24 to 30	15	15	5	24	3.3
★GP1A396HCPSF	<u></u> 本 * 文	Compact, high response speed, digital output, surface mount	1.2	0.12	2.85	-	2.5 to 5.5	24 to 30	15	15	5	24	3.3

Note: Topr = -25 to +85°C



<Case type> (Ta = 25°C)

			Detecting				Electro-	optical ch	aracterist	ics		
	Internal		and	Slit width	Thresho	old input o	urrent	F	ropagatio	n delay	time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	IFLH (mA) MAX.	IFHL (mA) MAX.	Vcc (V)	tpLн (µs) TYP.	tphL (µs) TYP.	IF (mA)	RL (Ω)	Vcc (V)
GP1A50HRJ00F		Both-side mounting, with screw hole	3.0	0.5	5	_	5	3	5	5	280	5
GP1A51HRJ00F	,—Voltage	Side mounting, with screw hole	3.0	0.5	5	_	5	3	5	5	280	5
GP1A52HRJ00F	regulator Amplifier	PWB mounting type	3.0	0.5	5	_	5	3	5	5	280	5
GP1A53HRJ00F	(When light is out off:	PWB mounting type	5.0	0.5	8	_	5	3	5	8	280	5
GP1A57HRJ00F	(When light is cut off: low level)	PWB mounting type, with positioning pin	10.0	1.8	7	-	5	3	5	7	280	5
GP1A58HRJ00F		PWB mounting type, with positioning pin	5.0	0.5	8	_	5	3	5	8	280	5
GP1A52LRJ00F	Voltage regulator Amplifier (When light is cut off: high level)	PWB mounting type	3.0	0.5	-	5	5	5	3	5	280	5

Note: Topr = -25 to +85°C





PHOTOINTERRUPTERS (TRANSMISSIVE TYPE)/(REFLECTIVE TYPE)



♦OPIC Type ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

<With 3-pin connector terminal>

 $(Ta = 25^{\circ}C)$

				Detecting			Electi	o-optical	characteri	stics	
	Internal	_		and	Slit width		voltage	Lo	w level ou	tput volta	ge
Model No.	connection diagram	Fe	eatures	emitting gap	(mm)		CC V)	Vol (V)	Light	lol	Vcc
				(mm)		MIN.	MAX.	MAX.	cut-off	(mA)	(V)
GP1A173LCS3F	-Voltage regulator Amplifier	3 V operation snap-in mour connector type	nting integrated	5.0	0.5	2.7	5.5	0.35	No	4	3.3
GP1A173LCSVF		Snap-in mou	nting integrated be*1, ctrostatic discharge	5.0	0.5	4.5	5.5	0.35	No	4	5

Note: Topr: -30 to +95°C
*1 Applicable to 3 kinds of thickness of mounting boards.



■ Photointerrupters

- <Reflective type>
- **♦**Single Phototransistor Output

<Compact>

 $(Ta = 25^{\circ}C)$

		lasta ana al		Optimum		Elec	tro-optica	l charact	eristics		
diagram distance (mm) CTR (%) IF VCE tr (μs) IC RL VCE VCE TYP. (mA) (kΩ) (VI TYP. (MA) (VI TYP. (VI TYP. (MA) (VI TYP. (VI TY	Model No		Features			nt transfer	ratio		Respon	ise time	
	Model No.		1 outures		OID (/0)						VCE (V)
	GP2S700HCP	* 5		4	1.5	4	2	20	0.1	1	2
GP2S60 Thin (3.2 × 1.7 × 1.1 [height] mm), surface mounting 1 1.0 4 2 20 0.1 1 2	GP2S60			1	1.0	4	2	20	0.1	1	2

Note: Topr: -25 to +85°C





PHOTOINTERRUPTERS (REFLECTIVE TYPE)

★ Under development



♦OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

<With 3-pin connector terminal>

(Ta = 25°C)

			0 .:		Е	lectro-opti	cal charac	teristics	
	Internal		Optimum detecting		voltage	Dissipation	n current	Low level or	utput voltage
Model No.	connection diagram	Features	distance (mm)	(\ MIN.	cc /) MAX.	Icc (mA) MAX.	Vcc (V)	Vol (V) MAX.	Vcc (V)
GP2A200LCS0F		Multiple types of paper detectable, light modulation type, with connector, sensitivity adjusted	5 to 15	4.75	5.25	30 ^{*1}	5	0.4	5
GP2A240LCS0F	(Following	Applicable to inverter fluorescent lamp, light modulation type, with connector, sensitivity adjusted	5 to 15	4.75	5.25	30 ^{*1}	5	0.4	5
GP2A250LCS0F	diagram [A])	Static electricity resistant, applicable to inverter fluorescent lamp, light modulation type, with connector, sensitivity adjusted	2.5 to 12.5	4.75	5.25	30 ^{*1}	5	0.4	5
GP2A25J0000F		Multiple types of paper detectable, light modulation type, with connector, sensitivity adjusted	3 to 7	4.75	5.25	30 ^{*1}	5	0.4	5
GP2A230LRS0F	(Following	Compact, screw-clamp type, multiple types of paper detectable, light modulation type, with connector		4.75	5.25	20 ^{*1}	5	0.4	5
GP2A230LRSAF	diagram [B])	Compact, hook type, multiple types of paper detectable,	3 to 7	4.73	3.23	20	3	0.4	J
★GP2A430LCSAF	(Following diagram [C])	light modulation type, with connector		3.0	5.5	10 ^{*1}	3.3 to 5	0.4	3.3 to 5
GP2A25NJJ00F	(F. II. :	Multiple types of paper detectable, light modulation type, sensitivity adjusted, improved light-resistance characteristic for inverter lighting, built-in visible light cut filter	3 to 7	4.75	5.25	30*1	5	0.4	5
GP2A25DJ000F	(Following diagram [A])	Multiple types of paper detectable, light modulation type, with connector, sensitivity adjusted	3 to 7	4.75	5.25	30 ^{*1}	5	0.4	5
GP2A28AJ000F		Multiple types of paper detectable, light modulation type, with connector, sensitivity adjusted, hook type	3 to 7	4.75	5.25	30 ^{*1}	5	0.4	5

Note: Topr: -10 to +60°C (GP2A25J0000F, etc.)
-10 to +70°C (GP2A200LCS0F, GP2A240LCS0F, GP2A250LCS0F, GP2A230LRS0F, GP2A230LRSAF, GP2A430LCSAF)

[Internal connection diagram] [A] Voltage regulator GP2A25J0000F (GP2A25NJJ00F, GP2A200LCS0F, GP2A240LCS0F GP2A250LCS0F Synchronous detector [B] Voltage regulator GP2A25DJ000F GP2A230LRS0F Synchronous detector [C] Voltage regulator GP2A230LRSAF [GP2A430LCSAF] GP2A28AJ000F

^{*1} Smoothing value R_L = ∞



PROXIMITY SENSOR / OPTO PROXIMITY SENSOR WITH INTEGRATED AMBIENT LIGHT SENSOR

☆ New product



■ Proximity Sensor

(Ta = 25°C)

		Absolute max	kimum ratings	E	Electro-optical	characteristic	S
Model No.	Features	Vcc (V)	Topr (°C)	Dissipation current Icc (μΑ) TYP.	Detecting distance Lon (mm) MIN.	Non- detecting distance Loff (mm) MAX.	Peak emission wavelength λp (nm)
GP2AP002S30F	Compact size (4.0 × 2.0 × 1.25 t mm) Drastically reduced LED current consumption by employing a light modulation system Built-in LEDs for simple optical design and I ² C output (LED emission duty: MAX. 0.3%)	3.8	-25 to +85	240	25	150	940



■ Proximity Sensor with Integrated Ambient Light Sensor

 $(Ta = 25^{\circ}C)$

			te maxi- ratings		E	lectro-optical	characteristic	cs	
					Proximity se	ensor portion	Ambier	it light sensor	portion
Model No.	Features	Vcc (V)	Topr (°C)	Dissipation current lcc (µA) TYP.	Detecting distance Lon (mm) TYP.	Peak emission wavelength λp (nm)	Recom- mended illuminance range Ev (lx)	Output resolution (bit)	ADC conversion time Tint (ms) TYP.
GP2AP030A00F	LED and ambient light sensor combined in a single package (4.0 × 2.1 × 1.25 t mm) Built-in LEDs for simple optical design Illuminance output: digital 16-bit output (Minimum detectable illuminance: 0.02 lx) I ² C output compatible (proximity sensor, ambient light sensor)	5.5	-35 to +85	65	100	940	0.02 to 10 000	16	100
☆GP2AP007A00F	LED and ambient light sensor combined in a single package (2.5 × 2.0 × 1.0 t mm) Compact with reduced mounting area Illuminance output: digital 16-bit output (Minimum detectable illuminance: 0.1 lx) Small aperture compatible I ² C output compatible (proximity sensor, ambient light sensor)	2.2 to 5.5	-30 to +85	100	100	940	0.1 to 100 000	16	30
☆GP2AP008T00F	LED and ambient light sensor combined in a single package (3.94 × 2.36 × 1.35 t mm) Illuminance output: digital 16-bit output (Minimum detectable illuminance: 0.1 lx) Small aperture compatible l²C output compatible (proximity sensor, ambient light sensor)	2.2 to 5.5	-30 to +85	100	100	940	0.1 to 100 000	16	30





PROXIMITY/GESTURE SENSOR WITH OPTO INTEGRATED AMBIENT LIGHT SENSOR / UV LIGHT SENSORS



■ Proximity/Gesture Sensor with Integrated Ambient Light Sensor

 $(Ta = 25^{\circ}C)$

			te maxi- ratings			Electro	o-optical cha	racteristics		
				Dissipa-	Dissipa- tion		//gesture portion	Ambient	t light senso	r portion
Model No.	Features	Vcc (V)	Topr (°C)	tion current Icc (µA) TYP.	current Icc (Gesture) (µA) TYP.	Detecting distance Lon (mm) TYP.	Peak emission wavelength λ p (nm)	Recom- mended illuminance range Ev (lx)	Output resolution (bit)	ADC conversion time Tint (ms) TYP.
GP2AP054A00F	LED and ambient light sensor combined in a single package (4.0 × 2.1 × 1.25 t mm) Simultaneous operation of the gesture recognition and illuminance functions is possible Low power consumption mode is available for the proximity sensor Capable of holding a total of 4 gesture detection results	5.5	-35 to +85	100	320	100	940	0.02 to 10 000	16	30



■ UV Light Sensors

 $(Ta = 25^{\circ}C)$

		Absolu	ıte maximum	ratings		E	lectro-optic	al characteri	stics
Model No.	Features	Vcc (V)	I ² C voltage VI ² C (V)		Dissipation current lcc (µA) TYP.	Built-in clock frequency fosc (MHz) TYP.	Output resolution (bit)	ADC conversion time (ms) TYP.	Recommended illuminance range Ev (lx) Sunlight (AM1.5 equivalent)
GA1AUV100WP	Detects only UV rays contained within sunlight (no sensitivity to visible light) Built-in ambient light sensor Compact size: 2.0 × 1.6 × 0.6 t mm I ² C output compatible	2.2 to 5.5	1.7 to Vcc	-35 to +85	65	2.62	16	25	UV: 0 to 200 000 Illuminance: 0 to 120 000





OPIC LIGHT DETECTORS



■OPIC Light Detectors ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

(Ta = 25°C)

			Absol	ute max	kimum r	atings			Electro	-optical	characte	eristics		
Model No.	Type	Package	Vcc	D	lo	Topr	Evlh	EVHL		tPLH	tPHL			
	,,,,,	. acitago	(V)	(mW)	(mA)	(°C)	(Ix) MAX.	(lx) MAX.	Vcc (V)	(µs) TYP.	(µs) TYP.	Vcc (V)	Ev (lx)	RL (Ω)
IS485E	Built-in schmidt trigger circuit, amplifier and	Transparent epoxy resin with	-0.5 to +17	175	50	-25 to +85	-	35	5	5	3	5	50	280
IS486E	voltage regulator	condenser (lens)	-0.5 to +17	175	50	-25 to +85	35	_	5	3	5	5	50	280



<Model employing a light modulation system>

 $(Ta = 25^{\circ}C)$

			Absol	ute max	imum r	atings		Electro-	optical ch	aracterist	tics*2		External
Model No.	Туре	Package	Vcc (V)	P (mW)	lo (mA)	Topr (°C)	VOL (V) MAX.	Voh (V) MIN.	tplh (µs) TYP.	tphL (µs) TYP.	Vcc (V)	RL (Ω)	disturbing light illuminance EVDX(Ix) TYP.
IS471FE*1, *3	Built-in pulse driver circuit at the emitter side, synchronous detector circuit, amplifier circuit and demodulator circuit	Visible light cut-off epoxy resin	-0.5 to +16	250	50	-25 to +60	0.35	4.97	400	400	5	280	7 000

^{*1} IS471FE is less susceptible to disturbing effects thanks to the light modulation system

^{*2} Vcc = 5 V
*3 Straight lead type (IS471FSE) is also available.



RoHS

PHOTOTRANSISTOR LINEUP /

PHOTOTRANSISTORS

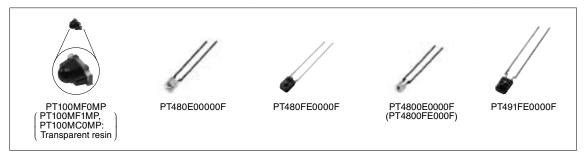
■ Phototransistor Lineup

			Half	Mod	lel No.
Package	Output type	Features	sensitivity angle	Standard	Visible light cut-off
Epoxy resin with lens	Single phototransistor	General purpose/Narrow acceptance	±13°	PT480E00000F	PT480FE0000F
		Compact, thin	±35°	PT4800E0000F	PT4800FE000F
	Darlington phototransistor	High sensitivity/Intermediate acceptance	±40°	_	PT491FE0000F
Surface mounting leadless type	Single phototransistor	Compact (side view/top view mounting possible)	±15°	PT100MC0MP	PT100MF0MP
	Darlington phototransistor	Compact (side view/top view mounting possible)	±15°	_	PT100MF1MP

■ Phototransistors

_O			Absol	ute maxin	num ratings		lc (r	mA)		ICEO	(A)	$\Delta \theta$	λp
Type	Model No.	Package	VCEO (V)	Pc (mW)	Topr (°C)	MIN.	MAX.	VCE (V)	Ee (mW/cm ²)	MAX.	VCE (V)	(°) TYP.	(nm) TYP.
	PT100MC0MP	Surface mounting	35	75	-30 to +85	1.7	5.1	5	1	1 × 10 ⁻⁷	20	±15	900
Ī	PT100MF0MP*1	leadless type with lens	35	75	-30 to +85	1.15	3.45	5	1	1 × 10 ⁻⁷	20	±15	910
Single	PT480E00000F		35	75	-25 to +85	0.4	TYP. 1.7	5	1	1 × 10 ⁻⁷	20	±13	800
Sin	PT480FE0000F*1	- Epoxy resin with lens	35	75	-25 to +85	0.25	TYP. 0.8	5	1	1 × 10 ⁻⁷	20	±13	860
	PT4800E0000F	Epoxy resilt with lens	35	75	-25 to +85	0.12	TYP. 0.4	5	1	1 × 10 ⁻⁷	20	±35	800
Ī	PT4800FE000F*1		35	75	-25 to +85	0.08	TYP. 0.25	5	1	1 × 10 ⁻⁷	20	±35	860
Darlington	PT491FE0000F*1	Epoxy resin with lens	35	75	-25 to +85	0.2	0.8	2	Ev, 2 lx	1 × 10 ⁻⁶	10	±40	860
Darlir	PT100MF1MP*1	Surface mounting leadless type with lens	35	75	-30 to +85	0.2	1.2	5	0.01	1 × 10 ⁻⁶	10	±15	860

^{*1} Visible light cut-off type





PIN PHOTODIODES



■ PIN Photodiodes

(Ta = 25°C)

		Package	Active	Topr	Isc		ld		tr, tf			λр
Model No.	Features	(Material)	area (mm²)	(°C)	(μA) MIN.	Ev (lx)	(A) MAX.	VR (V)	(µs) TYP.	VR (V)	RL (kΩ)	(nm) TYP.
PD410Pl2E00F	- PIN type	Visible light cut-off epoxy resin with condenser (lens)	3.31	-25 to +85	2.5	100	1 × 10 ⁻⁸	10	0.2	10	1	1 000
PD411PI2E00F	- Filv type	Transparent epoxy resin with condenser (lens)	3.31	-25 to +85	5.0	100	1 × 10 ⁻⁸	10	0.2	10	1	960
PD413Pl2E00F	PIN type IrDA1.0	Visible light cut-off epoxy resin with condenser (lens)	3.31	-25 to +85	MIN. 4.5 (TYP. 5.4)	100	1 × 10 ⁻⁸	10	0.2	10	1	960
PD100MC0MP	Surface mounting leadless type	Transparent epoxy resin board with lens	-	-30 to +85	0.6	100	1 × 10 ⁻⁸	10	0.01	15	0.18	820
PD100MF0MP	Surface mounting leadless type	Visible light cut-off epoxy resin board with lens	_	-30 to +85	0.4	100	1 × 10 ⁻⁸	10	0.01	15	0.18	850



PD410PI2E00F (PD411PI2E00F: transparent;) PD413PI2E00F



PD100MC0MP (PD100MF0MP: black)



INFRARED EMITTING DIODE LINEUP/ INFRARED EMITTING DIODES



■ Infrared Emitting Diode Lineup

Туре	Package	Feat	ures	Half intensity angle	Model No.
Single-end lead (Side view type)	Epoxy resin with lens	General purpose/Narrow bear	n angle	±13°	GL480E00000F
		Compact and thin		±30°	GL4800E0000F
Surface mount type	Epoxy resin with lens/ leadless	Compact/Narrow beam angle	T	±10°	GL100MN0MP
	(Mountable for Top view/ Side view type)		High output type	±10°	GL100MN1MP
		Compact/Wide beam angle		±80°	GL100MD1MP1

■ Infrared Emitting Diodes

(Ta = 25°C)

		Ab	solute	maximu	m ratings	Radia	nt flux Φe	(mW)	VF (V)			$\Delta\theta$	λр
Model No.	Package, features	IF (mA)	VR (V)	P (mW)	Topr (°C)	MIN.	TYP.	IF (mA)	TYP.	MAX.	IF (mA)	(°) TYP.	(nm) TYP.
GL480E00000F	- Epoxy resin with lens	50	6	75	-25 to +85	0.7	_	20	1.2	1.4	20	±13	950
GL4800E0000F	Lpoxy resin with lens	50	6	75	-25 to +85	0.7	1.6	20	1.2	1.4	20	±30	950
GL100MN0MP	Surface mounting leadless type, epoxy resin board with lens	50	6	75	-30 to +85	1.0	3.0 (MAX.)	20	1.2	1.4	20	±10	940
GL100MN1MP	Surface mounting leadless type, epoxy resin board with lens, high output type	50	6	75	-30 to +85	2.0	6.0 (MAX.)	20	1.2	1.5	20	±10	940
GL100MD1MP1	Surface mounting leadless type, epoxy resin board with lens, wide beam angle	50	6	75	-30 to +85	-	6.0 (MAX.)	20	-	1.5	20	±80	940





OPTICAL-ELECTRIC SENSOR LINEUP

★ Under development



■ Distance Measuring Sensor Lineup

Sensor type	Output	Detected distance	Features	Model No.
PSD, 2PD	1-bit digital output according to distance measuring	5 cm	Battery drive compatible, compact, 1-bit digital output	GP2Y0D805Z0F
		10 cm	Battery drive compatible, compact, 1-bit digital output	GP2Y0D810Z0F
		15 cm	Battery drive compatible, compact, 1-bit digital output	GP2Y0D815Z0F
		13 cm	1-bit digital output	GP2Y0D413K0F
		24 cm	1-bit digital output	GP2Y0D21YK0F
		80 cm	1-bit digital output	GP2Y0D02YK0F
	Analog voltage output according to distance measuring	1.5 to 15 cm	Analog output	GP2Y0AF15 series
	oaoag	2 to 15 cm	Analog output	GP2Y0A51SK0F
		4 to 30 cm	Analog output	GP2Y0A41SK0F / GP2Y0AF30 series
		10 to 80 cm	Analog output	GP2Y0A21YK0F
		10 to 150 cm	Compact (22 \times 8 \times 7.2 [T] mm), Analog output	GP2Y0A60SZLF
		20 to 150 cm	Analog output	GP2Y0A02YK0F
		100 to 550 cm	Analog output	GP2Y0A710K0F
CMOS	Analog voltage output according to distance measuring (Including I ² C output)	4 to 50 cm	Compact size, high-precision measurement Analog output	GP2Y0E02A
			I ² C output	GP2Y0E02B
			Analog, I ² C output	GP2Y0E03

■ Dust Sensor Unit Lineup

Output	Features	Model No.
Analog output	Pulse analog output, single-shot detection of house dust, general purpose	GP2Y1010AU0F
	Pulse analog output, single-shot detection of house dust, high sensitivity	GP2Y1012AU0F
Digital output	Digital (PWM) output, built-in microprocessor controller, single-shot detection of house dust, high sensitivity	GP2Y1023AU0F
	Digital (UART) output, built-in microprocessor controller, sensing can discriminate between PM2.5 and PM10, internal cleaning possible	★GP2Y1030AU0F





■ Distance Measuring Sensors (1) PSD, 2PD Type

♦Digital Output $(Ta = 25^{\circ}C)$

	D-44		Absolute max	ximum ratings	Ele	ctro-optical	characteristic	cs*1
Model No.	Detected distance (cm)	Features	Vcc (V)	Topr (°C)	Voh (V) MIN.	VOL (V) MAX.	Dissipation Operating (mA)	Standby (µA)
GP2Y0D805Z0F	5	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-10 to +60	Vcc -0.6	0.6	MAX. 6.5	MAX. 8
GP2Y0D810Z0F	10	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-10 to +60	Vcc -0.6	0.6	MAX. 6.5	MAX. 8
GP2Y0D815Z0F	15	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-10 to +60	Vcc -0.6	0.6	MAX. 6.5	MAX. 8
GP2Y0D413K0F	13	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, digital voltage output according to the measured distance	-0.3 to +7	-10 to +60	Vcc -0.3	0.6	_	-
GP2Y0D21YK0F	24	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, digital voltage output according to the measured distance	-0.3 to +7	-10 to +60	Vcc -0.3	0.6	MAX. 40	-
GP2Y0D02YK0F	80	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, long distance measuring type (No external control signal required), digital voltage output according to the measured distance	-0.3 to +7	-10 to +60	Vcc -0.3	0.6	MAX. 50	-

^{*1} Vcc = 5 V

^{*2} PSD: Position Sensitive Detector



DISTANCE MEASURING SENSORS



■ Distance Measuring Sensors (1) PSD, 2PD Type **♦** Analog Output

 $(Ta = 25^{\circ}C)$

			Absolute max	kimum ratings	Electro-o	ptical characte	ristics*1
Model No.	Distance measuring range	Features	Vcc (V)	Topr (°C)	Vон (V)	Vol (V)	Dissipation current
	(cm)		(V)	(0)	MIŃ.	MAX.	Operating (mA)
GP2Y0AF15 series	1.5 to 15	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, short measuring cycle (16.5 ms), compact, lineup of various connector shapes	-0.3 to +7	-10 to +60	Vo (TYP. (at L = - ΔVo (TYP (at L = 15 cn	15 cm), 2) = 2.3 V	TYP. 17
GP2Y0A51SK0F	2 to 15	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, short measuring cycle (16.5 ms)	-0.3 to +7	-10 to +60	Vo (TYP. (at L = Δ ΔVo (TYP. (at L = 15 c	15 cm),) = 2.25 V	TYP. 12
GP2Y0AF30 series	4 to 30	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, short measuring cycle (16.5 ms), compact, lineup of various connector shapes	-0.3 to +7	-10 to +60	Vo (TYP. (at L = 3 ΔVo (TYP (at L = 30 c	30 cm), 2) = 2.3 V	TYP. 17
GP2Y0A41SK0F	4 to 30	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, short measuring cycle (16.5 ms)	-0.3 to +7	-10 to +60	Vo (TYP. (at L = 3 ΔVo (TYP. (at L = 30 c	30 cm),) = 2.25 V	MAX. 22
GP2Y0A21YK0F	10 to 80	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, linear voltage output	-0.3 to +7	-10 to +60	Vo (TYP. (at L = 8 ΔVo (TYP (at L: 80 cm	30 cm), 2) = 1.9 V	MAX. 40
GP2Y0A60SZLF	10 to 150	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, compact type (22 x 8 x 7.2 mm), long distance measuring type (No external control signal required)	-0.3 to +5.5	-10 to +60	Vo (TYP.) (at L = 1 ΔVo (TYP (at L = 150 c	50 cm), c) = 3.0 V	MAX. 50
GP2Y0A02YK0F	20 to 150	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, long distance measuring type (No external control signal required)	-0.3 to +7	-10 to +60	Vo (TYP. (at L = 1 ΔVo (TYP. (at L = 150 c	, 50 cm),) = 2.05 V	MAX. 50
GP2Y0A710K0F	100 to 550	Distance measuring sensor united with PSD*2, infrared LED and signal processing circuit, long distance measuring type (No external control signal required)	-0.3 to +7	-10 to +60	Vo (TYP. (at L = 1 ΔVo (TYP (at L = 100 cr	, 00 cm), 2) = 0.7 V	TYP. 30

■ Distance Measuring Sensors (2) CMOS type ♦ Analog Output (Including I²C output)

 $(Ta = 25^{\circ}C)$

	D: .		Absolute max	kimum ratings	Electro-d	optical characte	ristics*1
Model No.	Distance measuring range	Features	Vcc	Topr	Voн	Vol	Dissipation current
	eignal process		(V)	(°C)	(V) MIN.	(V) MAX.	Operating (mA)
GP2Y0E02A	4 to 50	Infrared LED and CMOS image sensor with built-in signal processing circuit, compact size (18.9 \times 8 \times 5.2 mm), high-precision measurement, analog output	-0.3 to +3.6	-10 to +60	(at L = Vout (A) 3 =	= 0.3 to 0.8 V 50 cm), = 2.1 to 2.3 V = 4 cm)	MAX. 36
GP2Y0E02B	4 to 50	Infrared LED and CMOS image sensor with built-in signal processing circuit, compact size (18.9 \times 8 \times 5.2 mm), high-precision measurement, I ² C output	-0.3 to +3.6	-10 to +60	(at L = D3 = 3	to 50 cm 50 cm), to 5 cm : 4 cm)	MAX. 36
GP2Y0E03	4 to 50	Infrared LED and CMOS image sensor with built-in signal processing circuit, compact size (16.7 × 11 × 5.2 mm), high-precision measurement, analog / I ² C output both compatible	-0.3 to +5.5	-10 to +60	D1 = 45 (at L = Vout (A) 3 = D3 = 3	: 0.3 to 0.8 V, to 50 cm 50 cm), = 2.1 to 2.3 V, to 5 cm : 4 cm)	MAX. 36

^{*1} Vcc = 5 V

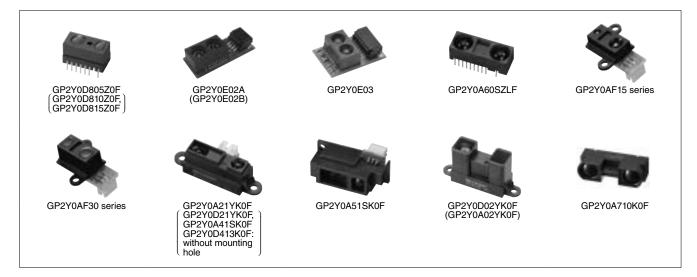
^{*2} PSD: Position Sensitive Detector *3 When Vcc = 3 V: Vo (TYP.) = 0.35 V (at L = 150 cm); Δ Vo (TYP.) = 1.6 V (at L = 150 cm \rightarrow 20 cm)



DISTANCE MEASURING SENSORS / DUST SENSOR UNIT

★ Under development





■ Dust Sensor Unit

 $(Ta = 25^{\circ}C)$

			Operating		Electro-optical c	haracteristics
Model No.	Features	Topr (°C)	supply voltage (V)	Dissipation current (mA)	Detection concentration µg/m³ (TYP.)	Output
GP2Y1010AU0F	Built-in infrared emitting diode, photodiode and signal processing circuit Compact, single-shot detection of house dust Output: Analog voltage		4.5 to 5.5	TYP. 11	0 to 600	Analog voltage
GP2Y1012AU0F	High sensitivity Built-in infrared emitting diode, photodiode and signal processing circuit Compact, single-shot detection of house dust Output: Analog voltage		4.5 to 5.5	TYP. 11	0 to 240	Analog voltage
GP2Y1023AU0F	High sensitivity Built-in microcomputer Built-in infrared emitting diode, photodiode and signal processing circuit Compact, single-shot detection of house dust Output: Digital signal output (PWM)	-10 to +65	4.75 to 5.25	TYP. 15	0 to 240	Digital signal (PWM) Temperature correction Averaging
★GP2Y1030AU0F	Built-in infrared emitting diode, photodiode and signal processing circuit Built-in microcomputer Sensing can discriminate between PM2.5 and PM10 Internal cleaning possible		3 to 5.5	TYP. 25	0 to 500	Digital signal (UART)



GP2Y1010AU0F (GP2Y1012AU0F, GP2Y1023AU0F)



GP2Y1030AU0F



IR DETECTING UNIT FOR REMOTE CONTROL LINEUP (CLASSIFIED BY FORM)



■ IR Detecting Unit for Remote Control Lineup (Classified by Form)

	Pac	kage			
Туре	Form	Detection position*1 (from PCB)	Features	Operating voltage	Model No.
	Lead L bend with				
detecting unit remote control	shield case (holder)	16.0 mm*2	Compact size	3 to 5 V	GP1UE28XK0VF series
			O O to a set o	5 V	GP1UM28XK0VF series
			Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	3 to 5 V	GP1UE28RK0VF series
				5 V	GP1UM28RK0VF series
		12.0 mm*3	Compact size	3 to 5 V	GP1UE27XK0VF series
			Compact size, Strengthened	5 V	GP1UM27XK0VF series
			resistance to electromagnetic induction noise (Mesh type)	3 to 5 V	GP1UE27RK0VF series
				5 V	GP1UM27RK0VF series
		6.8 mm*4	Compact size	3 to 5 V	GP1UE26XK0VF series
			Compact size, Strengthened	5 V	GP1UM26XK0VF series
			resistance to electromagnetic induction noise (Mesh type)	3 to 5 V	GP1UE26RK0VF series
	Lood atvaight		Compact size Strength and	5 V	GP1UM26RK0VF series
	Lead straight with shield case (holder)	19.0 mm	Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	3 to 5 V	GP1UE29QK0VF series
				5 V	GP1UM29QK0VF series
		9.6 mm	Compact size	3 to 5 V	GP1UE28YK0VF series
			Compact size, Strengthened	5 V	GP1UM28YK0VF series
			resistance to electromagnetic induction noise (Mesh type)	3 to 5 V	GP1UE28QK0VF series
				5 V	GP1UM28QK0VF series
	Holderless	Lead straight 6.0 mm		3 to 5 V	GP1UX31QS series
				5 V	GP1UX51QS series
		Lead L bend*5 5.3 mm		3 to 5 V	GP1UX31RK series
				5 V	GP1UX51RK series

^{*1} Lead straight: Distance from lens center to mounting board upper surface No mesh lead L bend: Distance from tip of lens to mounting board upper surface

No mesh lead L bend: Distance from tip of lens to mounting board upper surface

Mesh-type lead L bend: Distance from tip of mesh to mounting board upper surface

Mesh type (strengthened resistance to electromagnetic induction noise): 16.4 mm

Mesh type: 12.4 mm

Mesh type: 7.2 mm

To Mesh type: 5.3 mm



IR DETECTING UNITS FOR REMOTE CONTROL



■ IR Detecting Units for Remote Control

(Ta = 25°C)

		Absolute ma	ximum ratings	Operating	Ele	ctrical char	acteristics	3		
Туре	Series No.	Vcc (V)	Topr (°C)	voltage (V)	Icc (mA)*1 MAX.	Voh (V) MIN.	VOL (V) MAX.	fo (kHz) TYP.	Size (mm)	Terminal layout
	GP1UM26XK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	$5.6\times9.6\times6.8$	
With shield case (holder),	GP1UM27XK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 9.6 × 12.0	
5 V drive	GP1UM28XK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 9.6 × 16.0	
	GP1UM28YK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 8.6 × 12.5(9.6)*2	
	GP1UM26RK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	$5.6 \times 9.6 \times 7.2$	
With shield case (holder),	GP1UM27RK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 9.6 × 12.4	
5 V drive, Strengthened resistance to	GP1UM28RK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 9.6 × 16.4	
electromagnetic induction noise	GP1UM28QK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 9.0 × 12.5(9.6)*2	
	GP1UM29QK0VF	0 to 6.0	-10 to +70	4.5 to 5.5	0.6 (0.65)	Vcc-0.5	0.45	*3	5.6 × 16.2 × 21.9(19)*2	Center
	GP1UE26XK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	$5.6\times9.6\times6.8$	Vcc
With shield case (holder),	GP1UE27XK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 9.6 × 12.0	
3 to 5 V drive	GP1UE28XK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 9.6 × 16.0	
	GP1UE28YK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 8.6 × 12.5(9.6)*2	
	GP1UE26RK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	$5.6 \times 9.6 \times 7.2$	
With shield case (holder),	GP1UE27RK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 9.6 × 12.4	
3 to 5 V drive, Strengthened resistance to	GP1UE28RK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 9.6 × 16.4	
electromagnetic induction noise	GP1UE28QK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 9.0 × 12.5(9.6)*2	
	GP1UE29QK0VF	0 to 6.0	-10 to +70	2.7 to 5.5	0.4	Vcc-0.5	0.45	*3	5.6 × 16.2 × 21.9(19)*2	
Holderless, 5 V drive, Strengthened resistance to	GP1UX51QS	0 to 6.0	-10 to +70	4.5 to 5.5	0.6	Vcc-0.5	0.45	*3	5.5 × 5.3 × 7.5	
electromagnetic induction noise	GP1UX51RK	0 to 6.0	-10 to +70	4.5 to 5.5	0.6	Vcc-0.5	0.45	*3	$5.5 \times 5.3 \times 7.5$	Center
Holderless, 3 to 5 V drive, Strengthened resistance to	GP1UX31QS	0 to 6.0	-10 to +70	4.5 to 5.5	0.4	Vcc-0.5	0.45	*3	5.5 × 5.3 × 7.5	GND
electromagnetic induction noise	GP1UX31RK	0 to 6.0	-10 to +70	4.5 to 5.5	0.4	Vcc-0.5	0.45	*3	$5.5 \times 5.3 \times 7.5$	

Note: A voltage regulator circuit is built-in but may be affected by the usage environment. Install with an externally mounted C and R as a power supply filter.

^{*1} When no signal is input (during input light).
*2 Figures in parentheses indicate the distance to the light detection center.
*3 fo = 32.75/36/36.7/38/40 kHz



ZENIGATA LEDS FOR LIGHTING

☆ New product



■ Mini ZENIGATA LEDs (ZENIGATA is a registered trademark or a trademark of Sharp Corporation) in Japan, the United States and/or other countries.

<7W class>

 $(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW6BMG27HD6	2 700	34.5		830	83
	GW6BMG30HD6	3 000			885	
15.0 × 12.0 (t = 1.4)	GW6BMG40HD6	4 000		200	925	
(1 - 1.1)	GW6BGG27HD6	2 700		700 750	700	93
	GW6BGG30HD6	3 000			750	

<10W class> $(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW6BMW27HD6	2 700	34.5		1 200	83
	GW6BMW30HD6	3 000			1 280	
15.0×12.0 (t = 1.4)	GW6BMW40HD6	4 000		300	1 335	
(=)	GW6BGW27HD6	2 700			1 010	93
	GW6BGW30HD6	3 000			1 085	



<Natural toning type>

(Tj = 25°C)

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
15.0 × 12.0 (t = 1.6)	☆GW6NGWJCS0C	2 000	31	50	105	94
		3 000	36.5	350	1 000	92



Mini ZENIGATA LEDs (Natural toning type)



ZENIGATA LEDS FOR LIGHTING

☆ New product



■ Mega ZENIGATA LEDs (ZENIGATA is a registered trademark or a trademark of Sharp Corporation in Japan, the United States and/or other countries.

<17W class>	•			$(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	☆GW6DMB27BF6	2 700	34.5	500	2 200	
	☆GW6DMB30BF6	3 000			2 350	83
	☆GW6DMB35BF6	3 500			2 425	
24.0×20.0	☆GW6DMB40BF6	4 000			2 500	
(t = 1.45)	☆GW6DGB27BF6	2 700			1 900	93
	☆GW6DGB30BF6	3 000			1 975	
	☆GW6DGB35BF6	3 500			2 050	
	☆GW6DGB40BF6	4 000			2 200	

<25W class> $(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	☆GW6DMC27BF6	2 700	04.5	700	2 950	
	☆GW6DMC30BF6	3 000			3 150	83
	☆GW6DMC35BF6	3 500			3 250	
24.0×20.0	☆GW6DMC40BF6	4 000			3 350	
(t = 1.45)	☆GW6DGC27BF6	2 700	34.5	700	2 350	93
	☆GW6DGC30BF6	3 000			2 550	
	☆GW6DGC35BF6	3 500			2 750	
	☆GW6DGC40BF6	4 000			2 850	

<35W class> $(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	☆GW6DMD27BF6	2 700	34.5	252	4 050	83
	☆GW6DMD30BF6	3 000			4 200	
	☆GW6DMD35BF6	3 500			4 350	
24.0×20.0	☆GW6DMD40BF6	4 000			4 500	
(t = 1.45)	☆GW6DGD27BF6	2 700		950	3 300	93
	☆GW6DGD30BF6	3 000			3 450	
	☆GW6DGD35BF6	3 500			3 600	
	☆GW6DGD40BF6	4 000			3 750	

<45W class> $(Tj = 90^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.	
	☆GW6DME27BF6	2 700	46.1		5 150	82	
	☆GW6DME30BF6	3 000		950	5 550		
	☆GW6DME35BF6	3 500			5 750		
24.0×20.0	☆GW6DME40BF6	4 000			5 950		
(t = 1.45)	☆GW6DGE27BF6	2 700		930	4 350	93	
	☆GW6DGE30BF6	3 000			4 330		
	☆GW6DGE35BF6	3 500			4 750		
	☆GW6DGE40BF6	4 000			4 950	92	





ZENIGATA LEDS FOR LIGHTING

☆ New product



<Natural toning type>

 $(Tj = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
24.0 × 20.0 (t = 1.6)	☆GW6TGBJC50C	2 000	30.4	80	155	94
		3 000	35.8	950	2 860	92



■ TIGER ZENI LEDs

(Tj = 25°C)

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
24.0 × 20.0	GW6TGCBG40C	2 700	37	700	1 840	96
(t = 1.8)		5 700	38	700	2 170	90



TIGER ZENI LEDS



LEDs FOR LCD BACKLIGHTS



■ LEDs for Large-sized LCD Backlights (High Color Reproduction Models)

 $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color coordinates (x, y) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Color reproduction
4.2 × 1.4 (t = 0.8)	GM5FV1ZP10A	0.295, 0.275	3.0	80	26	
$3.7 \times 3.5 \ (t = 0.8)$	GM5F22BH20A	0.251, 0.210	6.51	160	86	sRGB=120% (CIE1976)*1
7.0 × 2.0 (t = 0.85)	GM5FQ0BH20A	0.266, 0.224	6.11	130	76.5	

^{*1} Evaluated using a general LCD panel. Values may differ depending on specific LCD panel characteristics.





☆ New product ★ Under development



■ Laser Diodes

◆Model ConfigurationsLaser diodes lineup

160

185

150

200

10

100

700

25

155

 25×2

210

700

700

210

285

SM

SM

SM

SM

SM

SM

MM

SM

SM

SM

SM

MM

MM

SM

MM

☆GH0631IA2G series

GH0641FA2G series

★GH0652AA2G series

GH06P25A2C

★GH0752WA2G

GH07825D2K

GH3S225D2B

★GH0832WA2G

★GH0852WA2G

★GH0942BA1K

☆GH0942IA2CC ★GH0942WA2G

☆GH0832BAxx series

					Package		
Wavelength (nm)	Absolute maximum ratings (mW)*1	Oscillation transverse mode *2	4				4
			ø5.6 mm Can type	ø3.8 mm Can type	ø3.3 mm Can type	1.8 mm t Frame type	1.2 mm t Frame type
405 band	20	SM	★GH04020D2AG	_	_	_	-
450 band	80	SM	★GH04580A2G	_	_	_	-
	7 / 10 / 15	SM	_	_	_	_	☆GH163xxxUK series
	30	SM	_	_	_	★GH16330A8C	-
	50	SM	_	-	_	★GH16350A8C	_
638 band	100	SM	_	_	_	★GH1631AA8C	-
	120	SM	-	★GH0631CA5G	_	_	-

★GH0631GA5G series

GH06510F4A

GH07P28F4C

☆GH0832BA4C

GH16P32C8C

★GH1832BA8C

★GH1942BA8C

642 band

650 band

660 band

750 band

785 band

830 band

850 band

940 band

2ch

• Eye-safe*1laser diodes lineup

				Package
Wavelength (nm)	Absolute maximum ratings (A)*2	Light output TYP. (mW)	Oscillation transverse mode*3	ø5.6 mm Eye-safe type
750 band	1	470 / 450	MM	★GH4757AxTG series
830 band	1	520 / 500	MM	☆GH4837AxTG series
850 band	1	520 / 500	MM	★GH4857AxTG series
940 band	1	370 / 330	MM	★GH4945AxTG series

^{*1} Laser with improved safety for eyes.

The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use. For CW (continuous wave)

SM: Single Mode

The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use. For CW (continuous wave) output.
*3 SM: Single Mode

MM: Multi Mode



☆ New product ★ Under development



♦ Specifications

Laser diodes

 $(Tc = 25^{\circ}C)$

Model No.	Wave-length (nm)	Absolute maximum ratings*1 (mW)	Operating temperature (°C)	Package size	Built-in monitor PD	Terminal connections	Applications	
★GH04020D2AG	405 band	20	tbd to +70	ø5.6 mm CAN	0	1	BD player	
★GH04580A2G	450 band	80	tbd to +70	ø5.6 mm CAN	_	8	Display, etc.	
☆GH163xxxUK series		7 / 10 / 15	-10 to +50	1.2 mm frame	0	10		
★GH16330A8C		30						
★GH16350A8C		50	-10 to +60	1.8 mm frame	_	6		
★GH1631AA8C	638 band	100					Display, etc.	
★GH0631CA5G		120	10 to . 00	~0.0 OAN				
★GH0631GA5G series		160	-10 to +60	ø3.8 mm CAN	_	8		
☆GH0631IA2G series		185	-10 to +65	ø5.6 mm CAN	_	9		
GH0641FA2G series	642 band	155	-10 to +60	ø5.6 mm CAN	_	8	Display, etc.	
★GH0652AA2G series	650 band	200	-10 to +60	ø5.6 mm CAN	_	9	Display, etc.	
GH06510F4A		10	-10 to +70	ø3.3 mm CAN	0	1	Bar code reader, laser displacement gauge, etc.	
GH16P32C8C	660 band	100	-10 to +70	1.8 mm frame		6	Various turnes of concern ato	
GH06P25A2C		100	-10 to +70	ø5.6 mm CAN		3	Various types of sensors, etc.	
★GH0752WA2G	750 band	700	-10 to +70	ø5.6 mm CAN	-	8	Various types of sensors, etc.	
GH07825D2K		25	-10 to +60	ø5.6 mm CAN	0	4	Printer, copier, MFP	
GH07P28F4C	785 band	155	-10 to +70	ø3.3 mm CAN	-	3	Various types of sensors, etc.	
GH3S225D2B		25 × 2	-10 to +60	ø5.6 mm CAN	0	5	Printer, copier, MFP	
☆GH0832BA2C			-10 to +70		-	3		
☆GH0832BA1K			-10 to +70	ø5.6 mm CAN		4		
☆GH0832BA2K	830 band	210	-10 10 +70		0	4	Various types of sensors, etc.	
☆GH0832BA4C	830 band		-10 to +70	ø3.3 mm CAN	_	3	Various types of sensors, etc.	
★GH1832BA8C			-10 to +70	1.8 mm frame	_	6		
★GH0832WA2G		700	-10 to +70	ø5.6 mm CAN	_	8		
★GH0852WA2G	850 band	700	-10 to +70	ø5.6 mm CAN	_	8	Various types of sensors, etc.	
★GH0942BA1K		010	-10 to +70	ø5.6 mm CAN	0	4		
★GH1942BA8C	040 bond	210	-10 to +70	1.8 mm frame	-	6	Various types of samears at-	
☆GH0942IA2CC	940 band	285	-10 to +65	ø5.6 mm CAN	_	3	Various types of sensors, etc.	
★GH0942WA2G		500	-10 to +70	יואט וווווו ס.כשר	_	8		

The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use. For CW (continuous wave) output.

• Eye-safe*1laser diodes

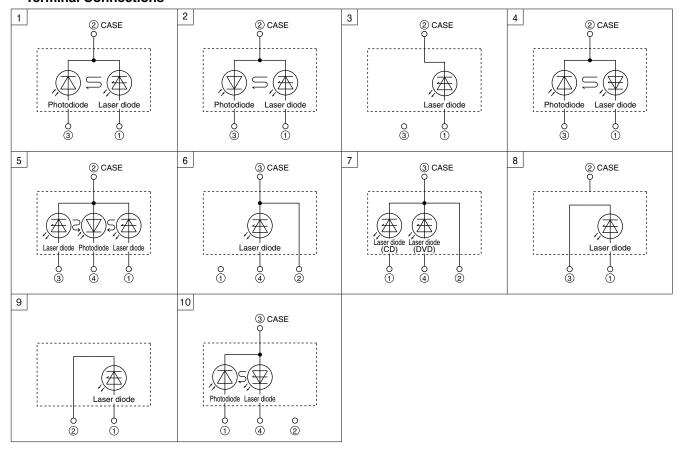
Model No.	Wavelength (nm)	Absolute maximum ratings (A)*2	Light output TYP. (mW)	Operating temperature (°C)	Package size	Built-in monitor PD	Terminal connections	Applications
★GH4757AxTG series	750 band		470 / 450					
☆GH4837AxTG series	830 band		520 / 500	tbd to +70	ø5.6 mm CAN		8	Various types of
★GH4857AxTG series	850 band	1	520 / 500	100 10 +70	Ø5.6 IIIII CAN	_	0	sensors, etc.
★GH4945AxTG series	940 band		370 / 330					

^{*1} Laser with improved safety for eyes.
*2 The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use. For CW (continuous wave) output.





• Terminal Connections



■ Europe: LNBs for Satellite Broadcast

◆ Features

- (1) Wide band type receiving all broadcasting channels (analog & digital) in Europe. [Universal LNB]
- (2) Originally developed feed-horn waveguide makes the wide-band, low-noise characteristics possible.
- (3) One of the industry's most compact and lightweight package.
- (4) Low dissipation current design for energy saving. [95 mA (TYP.): BS1K2EL100A]

♦ Specifications

Destination			Europe, Astra/Eut	telsat Satellite etc.			
Receiving polarization		Horizontal/Vertical polarization					
Model No. <type></type>		BS1K1EL500A <4-output>	BS1K2EL400A <4-output>	BS1K2EL200A <2-output>	BS1K2EL100A <1-output>		
Input frequency (GHz)			10.7 to 11.7 [Low band],	11.7 to 12.75 [High band]			
Output frequency (MHz)			950 to 1 950 [Low band],	1 100 to 2 150 [High band]			
Local oscillation frequen	cy (GHz)		9.75 [Low band],	10.6 [High band]			
NF (dB)			0.4 (TYP.)		0.3 (TYP.)		
Conversion gain (dB)		56 (TYP.)	58 (58 (TYP.)		
Phase noise (dBc/Hz)	Phase noise (dBc/Hz)		P.) at 1 kHz	.) at 1 kHz			
Cross-polar discrimination	on (dB)	25 (TYP.)					
Supply voltage (V DC)	Vertical polarization	11.5 to 14.0 (0/22 kHz)					
(Polarization switching)	Horizontal polarization		16.0 to 19.0) (0/22 kHz)			
Dissipation current (mA)		200 (TYP.)/250 (MAX.)	135 (TYP.)/300 (MAX.)	200 (TYP.)/250 (MAX.)	95 (TYP.)/120 (MAX.)		
Waveguide		Feed-horn (F/D = 0.6)					
Output impedance (Ω)		75					
Output connector (F-type)		4-output (H/H, H/L, V/H, V/L)	4-output (H/V, High and low switching)	2-output (H/V, High and low switching)	1-output (H/V, High and low switching)		
Outline dimensions (W)	× (D) × (H) (mm)	150 × 70 × 60	159 × 70 × 60	153 × 60 × 60	101 × 60 × 60		
Weight (g)		Approx. 190	Approx. 200	Approx. 145	Approx. 75		





■ Digital DBS Front-End Units

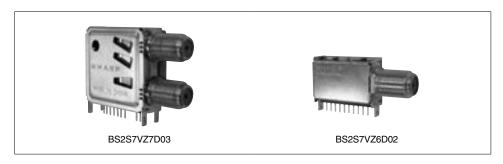
♦ Features

- (1) Equipped with a high-performance direct conversion IC. Reliability is improved by reducing power consumption and component
- (2) Wide-band reception design also covering CS broadcast band. [Input frequency: 950 to 2 150 MHz]
- (3) User support tools can be provided. [Sample/evaluation boards and software are available.]

♦ Standard Specifications <IQ output type>

Destination	Global (ISDB-S/DVB-S2/ABS-S)				
Input type	1-input/1-loop through output 1-input				
Model No.	BS2S7VZ7D03 BS2S7VZ6D02				
Input frequency (MHz)	950 to	2 150			
Input signal level (dBm)	−65 to) –25			
Base band frequency bandwidth (MHz)	5 to 40, 2 MHz step (BB LPF)				
RF input local leak (dBm)	-68 and below				
Output type	I/Q				
Noise figure (dB)	6 (TYP.)				
Phase noise (dBc/Hz)	-88 (TYP.) at 10 kHz offset				
Supply voltage (V DC)	3.3				
LNB power supply	DC 25 V, 400 mA (MAX.)				
Input impedance (Ω)	75				
Outline dimensions (mm)	30.4 (W) × 29.4 (D) × 12.9 (H) 25.2 (W) × 17.4 (D) × 8.7 (H)				

Note: Low-profile type is also available.







■ Front-End Units for ISDB-T/S

♦ Features

- (1) Low phase noise characteristics, high elimination of adjacent channel interference.
- (2) Compact, low power consumption.

♦ Standard Specifications

Destination	Japan (ISDB-T/S)							
Model No.	VA4S5	JD2358	VA4S6	JD2359	VA4S7	VA4S7JD2371		
	Digital terrestrial	Digital satellite	Digital terrestrial	Digital satellite	Digital terrestrial	Digital satellite		
Number of tuners	1	1	2	2	3	3		
Input frequency (MHz)	93 to 767	950 to 2 150	93 to 767	950 to 2 150	93 to 767	950 to 2 150		
Output type	DIF	I, Q	DIF	I, Q	DIF	I, Q		
Noise figure (dB)	4 (TYP.)	5 (TYP.)	4 (TYP.)	5 (TYP.)	4 (TYP.)	5 (TYP.)		
Phase noise (dBc/Hz)	-87 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset	-87 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset	-87 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset		
Supply voltage (V DC)	1.8, 3.3, 5	3.3	1.8, 3.3, 5	3.3	1.8, 3.3, 5	3.3		
Power consumption (W)	0.9	0.7	1.4	1.2	1.9	1.8		
Outline dimensions (mm)	41 (W) × 34 (D) × 8.75 (H)							



■ Front-End Units for DVB-T2/DTMB

♦ Features

- (1) Low phase noise characteristics, high elimination of adjacent channel interference.
- (2) Compact, low power consumption.
- (3) Other types are available with various chassis forms (vertical or horizontal type) and input connectors (F or DIN type), etc.

♦ Standard Specifications

Destination		Europe/Asia (DVB-T2), China (DTMB)				
Model No.	VA4M1DX2331	VA4M1DX2323	VA4M2DX2194			
Input frequency (MHz)	51 to	868	47 to 868			
Output type	DIF	DIF (Off through)	DIF (Dual output)			
Noise figure (dB)	5 (TYP.)					
Phase noise (dBc/Hz)		-90				
Supply voltage (V DC)	3.3	3.3, 1.8 5, 3.3, 1.8				
Power consumption (W)	0.49 1.13					
Outline dimensions (mm)	24.2 (W) × 25	24.2 (W) × 25.8 (D) × 8 (H) 41.3 (W) × 37.5 (D) × 12.3 (H				



Notice
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

FRONT-END UNITS FOR DIGITAL TERRESTRIAL AND **ANALOG TERRESTRIAL BROADCASTING**



■ Front-End Units for Digital Terrestrial and Analog Terrestrial Broadcasting

♦ Features

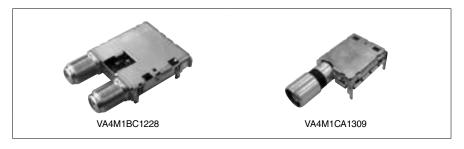
Contributing to the development of thinner LCD TVs and similar products by combining compatibility with digital and analog terrestrial broadcasts into a single unit.

♦ Standard Specifications

Destination	Brazil	China*1		
Model No.	VA4M1BC1228	VA4M1CA1309		
Input frequency (MHz)	47 to	866		
Output type	I	F		
Digital IF bandwidth (MHz)	6	8		
Phase noise (dBc/Hz)	-90 (TYP.) at 10 kHz offset			
Supply voltage (V DC)	3.3			
Noise figure (dB)	4 (TYP.)			
Channel selection system	PLL (I ² C-bus)* ²			
Outline dimensions (W) × (D) × (H) (mm)	30 × 28 × 7.5	26.2 × 20 × 10.6		

^{*1} Built-in isolator type

^{*2} I2C-bus is a trademark of Philips Corporation.



◆ Features

Universal specifications compatible with various broadcasting systems all over the world.

Digital: DVB-T/T2, DVB-C, ATSC, ISDB-T, DTMB Analog: NTSC-M/N, PAL-B/G/I/DK, SECAM-L, L'

♦ Standard Specifications

Destination	Global	
Model No.	VA4M1DB1370	
Input frequency (MHz)	47 to 868	
Output type	IF	
Noise figure (dB)	4 (TYP.)	
Phase noise (dBc/Hz)	-90 (TYP.)	
Supply voltage (V)	3.3	
Outline dimensions (W) × (D) × (H) (mm)	27 × 14 × 7.5	



Note: Contact SHARP for custom design product.

(For connector shape or facing side, analog output format, etc.)

ONE-SEG TUNER MODULE / DIGITAL TERRESTRIAL FRONT-END UNIT WITH EWBS

EWBS: Emergency Warning Broadcasting System



■ One-Seg Tuner Module

♦Features

(1) High sensitivity: -100 dBm (13 seg, QPSK CR: 2/3)

(2) Compact and thin design: $5.4 \times 5.4 \times 1.0$ mm

(3) Low power consumption: 41 mW (with software power control)

(4) Output interface: TS serial output



♦ Standard Specifications

Destination	Japan	
Model No.	VA3A5JZ967	
Input frequency (MHz)	470 to 770 (UHF: 13 to 62)	
Input signal level (dBm)	-100 (13 seg, QPSK CR: 2/3)	
Supply voltage (V DC)	1.2 (RF) 1.2 (OFDM Core) 1.62 to 3.6 (I/O)	
Power consumption (mW)	41 (TYP.)	
Operating temperature range (°C)	−20 to +65	
Control I/F	I ² C-bus* ¹	
Outline dimensions (mm)	5.4 (W) × 5.4 (D) × 1.0 (H)	

^{*1} I2C-bus is a trademark of Philips Corporation.

■ Digital Terrestrial Front-End Unit with EWBS

♦Features

- (1) Reduced power consumption with use of One-seg broadcasting system
- (2) Compact size for simple assembly



♦ Standard Specifications

Product name	Digital terrestrial front-end unit with EWBS			
Destination	Japan/Global (common)			
Model No.	VA4M1FB0337			
Reception bandwidth (MHz)	6/7/8			
Reception frequency range (MHz)	Full-seg tuner: (54 to 864), EWBS: UHF (470 to 862)			
Standby power consumption (mW)	Full-seg tuner: 690 (TYP.), EWBS: 63 (TYP.)			
Communication system	I ² C			
Power supply (V)	Full-seg tuner: 3.3, EWBS: 3.3, 1.2			
Outline dimensions (mm)	34 × 40.5 × 7.8			



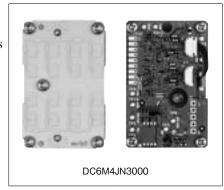
NON-CONTACT VITAL & MOTION SENSOR MODULE



■ Non-contact Vital & Motion Sensor Module

♦Features

- (1) Measures heart and breathing rate without contact using the Doppler effect.
- (2) The module can be embedded in products as sensing is possible through obstructions (except in cases where the obstructions are metal or metal plated).
- (3) Enables stable measurement without being affected by factors such as temperature, direct sunlight, or reflector color.



♦Standard Specifications

Model No.	DC6M4JN3000		
Output frequency (GHz)	24.05 to 24.5		
Output interface	UART interface (baud rate: 115 200; data bit length: 8 bits)		
Applications	Heart rate / Breathing rate / Body motion		
Measurable distance (m)	MAX. 1 (heart rate and breathing rate)		
Antenna	Planar antenna with 8 patch Tx / Rx antenna elements		
Antenna pattern (deg.)	30 (azimuth), 26 (elevation)		
Power supply (V)	3.3		
Dissipation current (mA)	100 (including signal processing)		
Outline dimensions (W)×(D)×(H) (mm)	RF module: 31 × 47.5 × 14.5 Signal processer: 30.0 × 46.5 × 5.0		

Sensor



■ PM2.5 Sensor Module

♦Features

- (1) Easy assembly for use in air purifiers and other products thanks to small size of $53 \times 40 \times 51$ mm
- (2) Industry's shortest*1 detection time of 10 seconds
- (3) Digital output model is also part of line-up
- *1 As of May 1, 2015 (measured by Sharp)



♦Standard Specifications

Model No.	DN7C3CA007 [Overseas]	DN7C3CD015 [Japan / Overseas]	
Measuring range (μg/m ³)	25 to 500 25 to 500		
Output type	Analog voltage Digital PWM		
Power supply voltage (Vcc/fan)	DC5 V / DC5 V	DC5 V / DC5 V	
Power consumption (mW) (TYP.)	At sensor: 55, At fan: 700 [JA001, CA006] 450 [CA007]	At sensor: 75, At fan: 450	
Output voltage range (V)	0 to 3.4 (MIN.) Vhigh: Vcc-1.5 (MIN.), Vlow: 1.3 (MAX.)		
Operating temperature range (°C)	-10 to +60 -10 to +60		
Outline dimensions (mm)	$53.0 \times 40.0 \times 51.0$ (excluding protruding parts) $53.0 \times 40.0 \times 51.0$ (excluding protruding		

■ Temperature and Humidity Sensor

♦Features

(1) Package: 3.0 x 3.0 x 0.8 mm, reflowable, QFN (2) High-speed response: Approx. 7 sec.*1

(3) Interface: I²C

*1 For 63% of humidity change



♦Standard Specifications

Model No.	QM1H0P0073			
Sensor	Humidity sensor Temperature sensor			
Туре	Macromolecule capacity Semiconductor			
Measuring range	0 to 100% RH -20 to +85°C			
Accuracy	±2% RH (25°C) ±0.3°C			
Resolution	0.1% RH 0.015°C			
Interface	I ² C			



	GH0942IA2CC54/55	GP1S093HCZ0F33	GP1UX51RK	49
BS	GH0942WA2G54/55	GP1S094HCZ0F33		
BS1K1EL500A57	GH1631AA8C54/55	GP1S097HCZ0F33	GP2	
BS1K2EL100A57	GH16330A8C54/55	GP1S173LCS2F34	GP2A200LCS0F	37
BS1K2EL200A57	GH16350A8C54/55	GP1S194HCZ0F33	GP2A230LRS0F	37
BS1K2EL400A57	GH163xxxUK series54/55	GP1S195HCPSF33	GP2A230LRSAF	37
BS2S7VZ6D0258	GH16P32C8C54/55	GP1S196HCPSF33	GP2A240LCS0F	37
BS2S7VZ7D0358	GH1832BA8C54/55	GP1S196HCZ0F33	GP2A250LCS0F	37
	GH1942BA8C54/55	GP1S273LCS1F34	GP2A25DJ000F	37
DC	GH3S225D2B54/55	GP1S296HCPSF33	GP2A25J0000F	37
DC6M4JN300062	GH4757AxTG series54/55	GP1S396HCP0F33	GP2A25NJJ00F	37
	GH4837AxTG series54/55	GP1S396HCPSF33	GP2A28AJ000F	37
DN	GH4857AxTG series54/55	GP1S50J0000F34	GP2A430LCSAF	37
DN7C3CA00763	GH4945AxTG series54/55	GP1S51VJ000F34	GP2AP002S30F	38
DN7C3CD01563		GP1S52VJ000F34	GP2AP007A00F	38
	GL	GP1S53VJ000F34	GP2AP008T00F	38
GA	GL100MD1MP143	GP1S56TJ000F34	GP2AP030A00F	38
GA1AUV100WP39	GL100MN0MP43	GP1S58VJ000F34	GP2AP054A00F	39
	GL100MN1MP43	GP1S59J0000F34	GP2S60	36
GH	GL4800E0000F43	GP1UE26RK0VF49	GP2S700HCP	36
GH04020D2AG54/55	GL480E00000F43	GP1UE26XK0VF49	GP2Y0A02YK0F	46
GH04580A2G54/55		GP1UE27RK0VF49	GP2Y0A21YK0F	46
GH0631CA5G54/55	GM5	GP1UE27XK0VF49	GP2Y0A41SK0F	46
GH0631GA5G series54/55	GM5F22BH20A53	GP1UE28QK0VF49	GP2Y0A51SK0F	46
GH0631IA2G series54/55	GM5FQ0BH20A53	GP1UE28RK0VF49	GP2Y0A60SZLF	46
GH0641FA2G series54/55	GM5FV1ZP10A53	GP1UE28XK0VF49	GP2Y0A710K0F	46
GH06510F4A54/55		GP1UE28YK0VF49	GP2Y0AF15 series	46
GH0652AA2G series54/55	GP1	GP1UE29QK0VF49	GP2Y0AF30 series	46
GH06P25A2C54/55	GP1A173LCS3F36	GP1UM26RK0VF49	GP2Y0D02YK0F	45
GH0752WA2G54/55	GP1A173LCSVF36	GP1UM26XK0VF49	GP2Y0D21YK0F	45
GH07825D2K54/55	GP1A396HCP0F35	GP1UM27RK0VF49	GP2Y0D413K0F	45
GH07P28F4C54/55	GP1A396HCPSF35	GP1UM27XK0VF49	GP2Y0D805Z0F	45
GH0832BA1K55	GP1A50HRJ00F35	GP1UM28QK0VF49	GP2Y0D810Z0F	45
GH0832BA2C55	GP1A51HRJ00F35	GP1UM28RK0VF49	GP2Y0D815Z0F	45
GH0832BA2K55	GP1A52HRJ00F35	GP1UM28XK0VF49	GP2Y0E02A	46
GH0832BA4C54/55	GP1A52LRJ00F35	GP1UM28YK0VF49	GP2Y0E02B	46
GH0832BAxx series54	GP1A53HRJ00F35	GP1UM29QK0VF49	GP2Y0E03	46
GH0832WA2G54/55	GP1A57HRJ00F35	GP1UX31QS49	GP2Y1010AU0F	47
GH0852WA2G54/55	GP1A58HRJ00F35	GP1UX31RK49	GP2Y1012AU0F	47
GH0942BA1K54/55	GP1S092HCPIF33	GP1UX51QS49	GP2Y1023AU0F	47



GP2Y1030AU0F	47	GW6DMD40BF6	51	LQ085Y3DG18	2	LQ231U1LW32	4
		GW6DME27BF6	51	LQ091B1LW01	2	LQ270M1LX01	4
GW6		GW6DME30BF6	51				
GW6BGG27HD6	50	GW6DME35BF6	51	LQ1		LQ3	
GW6BGG30HD6	50	GW6DME40BF6	51	LQ101K1LY05	2	LQ315D1JG95	5
GW6BGW27HD6	50	GW6NGWJCS0C	50	LQ101W3LG01	2	LQ315D1VG01	5
GW6BGW30HD6	50	GW6TGBJC50C	52	LQ104S1DG2C	2		
GW6BMG27HD6	50	GW6TGCBG40C	52	LQ104S1LG81	2	LQ6	
GW6BMG30HD6	50			LQ104V1DG81	2	LQ695D1VG03	5
GW6BMG40HD6	50	IR		LQ104V1LG81	2	LQ695D1VG04	5
GW6BMW27HD6	50	IR2E58U	15	LQ121K1LG52	3	LQ695D3LG03	5
GW6BMW30HD6	50	IR2E67M	15	LQ121K1LG58	3	LQ695D3LG06	5
GW6BMW40HD6	50	IR2E70N	15	LQ121K1LW56	3	LQ695D3LG07	5
GW6DGB27BF6	51	IR2E71Y	15	LQ121S1DG81	3		
GW6DGB30BF6	51	IR3M92N4	16	LQ121S1LG84	3	LQ9	
GW6DGB35BF6	51			LQ121S1LG86	3	LQ900D3LA01	5
GW6DGB40BF6	51	IS		LQ121X3LG02	3	LQ900D3LA03	5
GW6DGC27BF6	51	IS471FE	40	LQ150X1LG11	3		
GW6DGC30BF6	51	IS485E	40	LQ150X1LG91	3	LR0	
GW6DGC35BF6	51	IS486E	40	LQ150X1LG96	3	LR0G964	14
GW6DGC40BF6	51			LQ150X1LW12	3	LR0G967	14
GW6DGD27BF6	51	LK		LQ150X1LW95	3	LR0G970	14
GW6DGD30BF6	51	LK800D3LA28	5	LQ150X1LW96	3	LR0G971	14
GW6DGD35BF6	51	LK800D3LA38	5	LQ150X1LX92	3		
GW6DGD40BF6	51	LK800D3LA48	5	LQ150X1LX95	3	LR3	
GW6DGE27BF6	51			LQ150X1LX96	3	LR36B16	11/12
GW6DGE30BF6	51	LQ0		LQ150X1LX9K	3	LR388K4	14
GW6DGE35BF6	51	LQ035Q3DG03	2	LQ156M1LG21	4		
GW6DGE40BF6	51	LQ035Q3DY01	2	LQ156M3LW01	4	LS	
GW6DMB27BF6	51	LQ042T1DW01	2	LQ156T3LW03	4	LS010B7DH05	6
GW6DMB30BF6	51	LQ043T1DG28	2	LQ185M3LW01	4	LS012B7DH02	6
GW6DMB35BF6	51	LQ043T1DG29	2	LQ190E1LW52	4	LS013B7DH03	6
GW6DMB40BF6	51	LQ043Y1DY01	2	LQ190E1LW72	4	LS013B7DH05	6
GW6DMC27BF6	51	LQ057Q3DC03	2	LQ190E1LX75	4	LS013B7DH06	6
GW6DMC30BF6	51	LQ064V3DG06	2	LQ190E1LX75T	4	LS027B7DH01	6
GW6DMC35BF6	51	LQ064X3LW01	2	LQ190N1LW01	4	LS037V7DW05	2
GW6DMC40BF6	51	LQ070Y3LG01	2			LS037V7DW06	2
GW6DMD27BF6	51	LQ070Y3LW01	2	LQ2		LS044Q7DH01	6
GW6DMD30BF6	51	LQ084S3LG03	2	LQ201U1LW31	4		
GW6DMD35BF6	51	LQ084V1DG43	2	LQ201U1LW32	4		



RJ31N3EA0DT.....8

		FROUNTS INSLF	NJ31N3EAUD10
PC1	PC4	PR39MF22NSZF31	RJ31N3ED0DT8
PC1231xNSZ0X24	PC400J00000F25	PR39MF51NSLF31	RJ31N4AA0DT8
PC123XNNSZ0F24	PC451J00000F22	PR3BMF51NSLF31	RJ31N4AD0DT8
	PC452J00000F22	PR3BMF52NSZF31	RJ31N4EA0DT8
PC2	PC457L0NIP0F25		RJ31N4ED0DT8
PC2SD11NTZAF28	PC4SD11NTZCF28	PT	RJ31P3AA0DT8
	PC4SD21NTZCF29	PT100MC0MP41	RJ31P3AD0DT8
PC3	PC4SD21NTZDF29	PT100MF0MP41	RJ31P4AA0DT8
PC354NJ0000F22	PC4SF11YTZBF28	PT100MF1MP41	RJ31P4AD0DT8
PC355NJ0000F22	PC4SF21YVZBF29	PT4800E0000F41	RJ32S3AA0DT9
PC357NJ0000F22	PC4SF21YWPSF29	PT4800FE000F41	RJ32S3AD0DT9
PC364NJ0000F22		PT480E00000F41	RJ32S3AF0DT9
PC365NJ0000F22	PC8	PT480FE0000F41	RJ32S4AA0DT9
PC367NJ0000F22	PC815XNNSZ0F24	PT491FE0000F41	RJ32S4AD0DT9
PC3H3J00000F23	PC8171xNSZ0X24		RJ32S4AF0DT9
PC3H41xNIP0F23	PC817XNNSZ0F24	QM	RJ3331AA0PB8
PC3H4J00000F23	PC851XNNSZ0F24	QM1H0P007363	RJ3341AA0PB8
PC3H510NIP0F23	PC852XNNSZ0F24		RJ33B3AA0DT8
PC3H5J00000F23		RJ	RJ33B3AD0DT8
PC3H71xNIP0F23	PC9	RJ2315EA0PB10/12	RJ33B4AA0DT8
PC3H7J00000F23	PC900V0NSZXF26	RJ2315FA0PB10/12	RJ33B4AD0DT8
PC3HU7xYIP0B23	PC925LENSZ0F26	RJ2325EA0PB10/12	RJ33J3CA0DT8
PC3SD11NTZCF28		RJ2325FA0PB10/12	RJ33J4CA0DT8
PC3SD11YTZCF28	PD	RJ2331BA0PB10/12	RJ33N3AA0LT8
PC3SD12NTZAF28	PD100MC0MP42	RJ2331CA0PB10/12	RJ33N3AD0LT8
PC3SD13YXZBF28	PD100MF0MP42	RJ2341BA0PB10/12	RJ33N4AA0LT8
PC3SD21NTZAF29	PD410Pl2E00F42	RJ2341CA0PB10/12	RJ33N4AD0LT8
PC3SD21NTZBF29	PD411PI2E00F42	RJ2355DA0PB10/12	RJ3DT3AA0DT9
PC3SD21NTZDF29	PD413PI2E00F42	RJ2355EA0PB10/12	RJ3DT3AD0DT9
PC3SF11YVZAF28		RJ2365DA0PB10/12	RJ3DT3AF0DT9
PC3SF11YVZBF28	PR	RJ2365EA0PB10/12	RJ3DT4AA0DT9
PC3SF21YVZAF29	PR22MA11NTZF31	RJ2411FA0PB10/12	RJ3DT4AD0DT9
PC3SF21YVZBF29	PR31MA11NTZF31	RJ2421FA0PB10/12	RJ3DT4AF0DT9
PC3SH11YFZAF28	PR32MA11NTZF31	RJ2431AA0PB10/12	RJ3DV3AF0DT9
PC3SH13YFZAF28	PR33MF51NSLF31	RJ2441AA0PB10/12	RJ3DV4AF0DT9
PC3SH21YFZBX29	PR33MF52NSLF31	RJ2455DA0PB10/12	RJ3EV3EF0DT9
PC3ST11NSZKF28	PR36MF12NSZF31	RJ2465DA0PB10/12	RJ3EV4EF0DT9
	PR36MF21NSZF31	RJ31N3AA0DT8	RJ52N1BA0LT7
	PR36MF22NSZF31	RJ31N3AD0DT8	RJ52N2BA0LT7

PR36MF51NSLF31



RJ5DY1BA0LT7				
RJ5DY2BA0LT7				
S2				
S2S3A00F28				
S2S4A00F29				
S2S5A00F28				
S2S5FA0F28				
VA				
VA3A5JZ96761				
VA3A5JZ96761				
VA3A5JZ96761 VA4M1BC122860				
VA3A5JZ967				
VA3A5JZ967				
VA3A5JZ967				

 NOTE



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JQA-EM7240

The following facilities of Sharp Corporation have been certified under the ISO 14001 international standard for environmental management systems. In our products and manufacturing processes, we are actively engaged in environmental preservation efforts

Facility	Certificate Mark	Certificate No.	Scope of Registered Activities
Advanced Development and Planning Center	1	EC99J2038	Research and development, production technology development, and manufacture of LCD panels The manufacture of compact LCD panels
Mie Plant	1	EC99J2051	Development, design and manufacture of LCDs
Kameyama Plant	1	EC04J0284	Development and production of LCD
Electronic Components and Devices Company (Fukuyama)	2	JQA-EM7239	Design, development and manufacture of electronic devices
Electronic Components and Devices Company (Mihara)	2	JQA-EM7240	Design, development and manufacture of laser diodes, hologram laser and LED devices



The following groups of Sharp Corporation have been certified under the ISO 9001:2008 international standard for quality management systems.

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Certifying organization: Japan Quality Assurance Organization (JQA) [JAB certified]			
Group	Certificate No.	Scope of Registered Activities	
Electronic Components and Devices Company	JQA-QM8688	The Sales, design/development and manufacturing of the following products. Integrated circuits, RF devices, Opto-electronic devices, module, camera module, application products of camera module, LED, application products of LED, laser diodes, hologram laser	
Display Device Company	JQA-QM3776	The design / development and manufacture of Liquid crystal display panel and module	

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